

TDP158 6Gbps、交流耦合型 TMDS™ 或 HDMI™ 电平转换器转接驱动器

1 特性

- 交流耦合 TMDS 或 DisplayPort™ 双模物理层输入到 HDMI2.0b TMDS 物理层输出，支持高达 6Gbps 的数据速率，兼容 HDMI2.0b 电气参数
- 支持 DisplayPort 双模标准版本 1.1
- 支持 4k2k60p 和高达 WUXGA 16 位色深或 1080p，刷新率更高
- 可编程固定接收器均衡器增益最高可达 15.5dB
- 全局或独立的高速通道控制、预加重和发送摆幅以及转换率控制
- I²C 或引脚搭接可编程
- 可通过 I²C 配置为 DisplayPort 转接驱动器
- 主通道上全通道交换
- 低功耗
 - 6Gbps 时的工作功耗为 200mW，关断状态下的功耗为 8mW
- 采用 40 引脚、0.4mm 间距、5mm x 5mm WQFN 封装，与 SN75DP159RSB 重计时器引脚兼容

2 应用

- 笔记本电脑、台式机、一体机、平板电脑、游戏机和工业 PC
- 音频或视频设备
- Blu-ray™ DVD
- 游戏系统
- HDMI 适配器或软件狗
- 集线站

3 说明

TDP158 器件是一款交流耦合型 HDMI 信号转最小化传输差分信号 (TMDS) 转接驱动器，支持数字视频接口 (DVI) 1.0 和高清多媒体接口 (HDMI) 1.4b 和 2.0b 输出信号。TDP158 支持四条 TMDS 通道和数字显示控制 (DDC) 接口。TDP158 支持高达 6Gbps 的信号传输速率，可实现高达 4k2k60p 24 位/像素的分辨率以及高达 WUXGA 16 位色深或 1080p，同时具有较高的刷新率。TDP158 经配置可支持 HDMI2.0 标准。

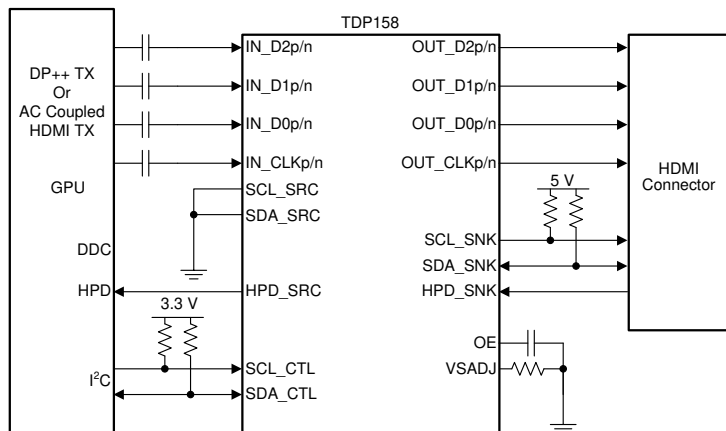
TDP158 支持双电源轨

(V_{DD} 为 1.1V, V_{CC} 为 3.3V)，有助于降低功耗。该器件采用多种电源管理方法降低整体功耗。TDP158 通过 I²C 或引脚搭接支持固定接收器 EQ 增益，从而补偿长度不同的输入电缆或电路板引线。

器件信息(1)

器件型号	封装	封装尺寸 (标称值)
TDP158	WQFN (40)	5.00mm × 5.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



Copyright © 2016, Texas Instruments Incorporated

简化版原理图



显示



Table of Contents

1 特性	1	8.1 Overview.....	19
2 应用	1	8.2 Functional Block Diagram.....	20
3 说明	1	8.3 Feature Description.....	20
4 Revision History	2	8.4 Device Functional Modes.....	27
5 Pin Configuration and Functions	4	8.5 Register Maps.....	28
6 Specifications	6	9 Application and Implementation	40
6.1 Absolute Maximum Ratings.....	6	9.1 Application Information.....	40
6.2 ESD Ratings.....	6	9.2 Typical Application.....	40
6.3 Recommended Operating Conditions.....	6	10 Power Supply Recommendations	46
6.4 Thermal Information.....	7	10.1 Power Management.....	46
6.5 Electrical Characteristics, Power Supply.....	8	10.2 Standby Power.....	46
6.6 Electrical Characteristics, Differential Input.....	9	11 Layout	47
6.7 Electrical Characteristics, TMDS Differential Output.....	9	11.1 Layout Guidelines.....	47
6.8 Electrical Characteristics, DDC, I2C, HPD, and ARC.....	9	11.2 Layout Example.....	48
6.9 Electrical Characteristics, TMDS Differential Output in DP-Mode.....	10	12 Device and Documentation Support	49
6.10 Switching Characteristics, TMDS.....	10	12.1 Documentation Support.....	49
6.11 Switching Characteristics, HPD.....	10	12.2 接收文档更新通知.....	49
6.12 Switching Characteristics, DDC and I ² C.....	11	12.3 支持资源.....	49
6.13 Typical Characteristics.....	12	12.4 Trademarks.....	49
7 Parameter Measurement Information	13	12.5 Electrostatic Discharge Caution.....	49
8 Detailed Description	19	12.6 术语表.....	49
		13 Mechanical, Packaging, and Orderable Information	49

4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (March 2020) to Revision E (July 2022)	Page
• 更新了整个文档中的表格、图和交叉引用的编号格式.....	1
• 在整个数据表中添加了包容性术语.....	1
• Updated the <i>TDP158 in Source Side Application</i> figure with ESD between device and receptacle.....	40
• Updated the <i>TDP158 Source Side Application with DDC Snoop</i> figure with ESD between device and receptacle.....	44
• Updated the <i>TDP158 in Dual Role Source Side Application</i> figure with ESD between device and receptacle....	45
Changes from Revision C (October 2019) to Revision D (March 2020)	Page
• 将 HDMI 2.0a 更改为 HDMI 2.0b.....	1
Changes from Revision B (June 2017) to Revision C (October 2019)	Page
• 删除了 <i>特性</i> ：面向商业和工业应用的扩展温度器件选项.....	1
• 更改了 <i>特性</i> ：从“与 SN65DP159RSB 和 SN75DP159RSB 重计时器引脚兼容”更改为“与 SN75DP159RSB 重计时器引脚兼容”.....	1
• 从 <i>器件信息</i> 表中删除了 TDP158I.....	1
• Changed the T _J MIN value From: - 40°C To: 0°C in the <i>Recommended Operating Conditions</i> table.....	6
• Deleted T _A for TDP158I in the <i>Recommended Operating Conditions</i> table.....	6
• Changed the last sentence of the <i>Overview</i> section to remove the TDP158I device.....	19
Changes from Revision A (January 2017) to Revision B (June 2017)	Page
• 将标题从“HDMI™ 转接驱动器”更改为“HDMI™ 电平转换器转接驱动器”.....	1

- 更改了特性列表..... 1
- 更改了应用列表..... 1
- Added text to pins 17, 23, 34, 16 in the *Pin Functions* table: "For pin control, Low = 1 k Ω pulldown resistor to GND, High = 1 k Ω pullup resistor to VCC, NC = Floating"4
- Added text to pin NC in the *Pin Functions* table: "Optionally connect 0.1 μ F to GND to reduce noise".....4
- V_{SADJ}: Added Note "Reducing resistor ..", and Changed values in the *Recommended Operating Conditions* table..... 6
- Changed Rvsdj max value to 8 k Ω in 图 6-1 12
- Changed the paragraph in the *Operation Timing* section..... 21
- Added column Pin Number to 表 8-2, Changed IN_CLK \rightarrow OUT_CLK To: IN_D2 \rightarrow OUT_D2 in the last row of the SWAP column..... 22
- Changed Note 1 of 表 8-3 23
- Changed the last two sentences of the paragraph in the *pre-emphasis* section..... 26
- Changed the title of 图 8-6 From: 3.5 dB pre-emphasis in Normal Operation To: 6 dB pre-emphasis Setting in Normal Operation..... 26
- Changed From: Reg0Ch[1:0] = 01 To: Reg0Ch[1:0] = 10 in 图 8-7 26
- Changed the Default setting in 表 8-9 From: TBD To: 00000001..... 30
- Added paragraph to the *Application and Implementation* section: "TDP158 is designed .."..... 40
- Changed the *Application Information* paragraph..... 40
- Changed From: 0 Ω resistors To: 1 k Ω resistors, and a noise filter (capacitor) for the no connect in 图 9-1 40
- Added text "1 k Ω pulldown resistor " to the Connect values in 表 9-1 41
- Changed text in the second paragraph of the *Source Side HDMI Application* section From: "Control pins can be tied directly to VCC, GND or left floating." To: "Control pins should be tied to 1 k Ω pullup to VCC, 1 k Ω pulldown to GND, or left floating."..... 44
- Changed From: 0 Ω resistors To: 1 k Ω resistors, and a noise filter (capacitor) for the no connect in 图 9-5 44
- Changed From: 0 Ω resistors To: 1 k Ω resistors, and a noise filter (capacitor) for the no connect in 图 9-6 45
- Changed From: 0 Ω resistors To: 1 k Ω resistors, and a noise filter (capacitor) for the no connect in 图 11-2 ... 48

Changes from Revision * (December 2016) to Revision A (January 2017)	Page
• 将“预览”更改为量产数据.....	1

5 Pin Configuration and Functions

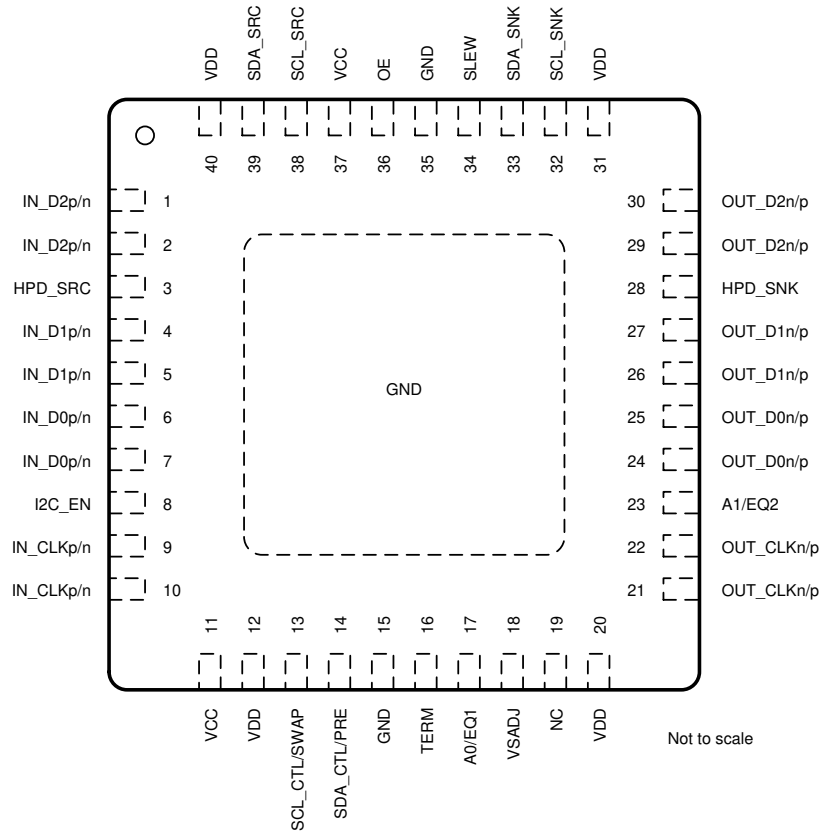


图 5-1. RSB Package, 40-Pin WQFN (Top View)

表 5-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
SUPPLY AND GROUND PINS			
VCC	11, 37	P	3.3 V Power Supply
VDD	12,20,31,40	P	1.1 V Power Supply
GND	15, 35 Thermal Pad	G	Ground
MAIN LINK INPUT PINS			
IN_D2p/n	1, 2	I	Channel 2 Differential Input
IN_D1p/n	4, 5	I	Channel 1 Differential Input
IN_D0p/n	6, 7	I	Channel 0 Differential Input
IN_CLKp/n	9, 10	I	Clock Differential Input
MAIN LINK OUTPUT PINS (FAIL SAFE)			
OUT_D2n/p	29, 30	O	TMDS Data 2 Differential Output
OUT_D1n/p	26, 27	O	TMDS Data 1 Differential Output
OUT_D0n/p	24, 25	O	TMDS Data 0 Differential Output
OUT_CLKn/p	21, 22	O	TMDS Data Clock Differential Output

表 5-1. Pin Functions (continued)

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
HOT PLUG DETECT AND DDC PINS			
HPD_SRC	3	O	Hot Plug Detect Output to source side
HPD_SNK	28	I	Hot Plug Detect Input from sink side
SDA_SNK	33	I/O	Sink Side Bidirectional DDC Data Line
SCL_SNK	32	I/O	Sink Side Bidirectional DDC Clock Line
SDA_SRC	39	I/O	Source Side Bidirectional DDC Data Line
SCL_SRC	38	I/O	Source Side Bidirectional DDC Clock Line
CONTROL PINS			
OE	36	I	Operation Enable/Reset Pin OE = L: Power Down Mode OE = H: Normal Operation Internal weak pullup: Resets device when transitions from H to L
I2C_EN	8	I	I2C_EN = High; Puts Device into I2C Control Mode I2C_EN = Low; Puts Device into Pin Strap Mode
SDA_CTL/PRE	14	I/O	I2C Data Signal: When I2C_EN = High; Pre-emphasis: When I2C_EN = Low: See # 8.3.11 DE = L: None 0 dB DE = H: 3.5 dB
SCL_CTL/SWAP	13	I	I2C Clock Signal: When I2C_EN = High; Lane SWAP: When I2C_EN = Low: See # 8.3.4 HDMI Mode Only SWAP = L: Normal Operation SWAP = H: Lane Swap
VSADJ	18	I	TMDS Compliant Voltage Swing Control (Nominal 6 k Ω for HDMI and DP combination; 6.49 k Ω for HDMI only)
A0/EQ1	17	I 3 Level	Address Bit 1 for I2C Programming when I2C_EN = High EQ1 Pin Setting when I2C_EN = Low; Works in conjunction with A1/EQ2; See # 8.3.5 for settings. For pin control, Low = 1 k Ω pulldown resistor to GND, High = 1 k Ω pullup resistor to VCC, NC = Floating.
A1/EQ2	23	I 3 Level	Address Bit 2 for I2C Programming when I2C_EN = High EQ2 Pin Setting when I2C_EN = Low; Works in conjunction with A0/EQ1; See # 8.3.5 for settings. For pin control, Low = 1 k Ω pulldown resistor to GND, High = 1 k Ω pullup resistor to VCC, NC = Floating.
SLEW	34	I 3 Level	Clock Slew Rate Control: See # 8.3.10 SLEW = L: Slowest \approx 203 ps SLEW = NC (Default): Mid-range 1 \approx 180 ps SLEW = H: Fastest \approx 122 ps For pin control, L = 1 k Ω pulldown resistor to GND, H = 1 k Ω pullup resistor to VCC, NC = Floating.
TERM	16	I 3 Level	Source Termination Control: See # 8.3.8 TERM = H, 75 Ω \approx 150 Ω TERM = L, Transmit Termination impedance in 150 Ω \approx 300 Ω TERM = NC, No transmit Termination Note: When TMDS_CLOCK_RATIO_STATUS bit = 1 the TDP158 sets source termination to 75 Ω \approx 150 Ω Automatically For pin control, L = 1 k Ω pulldown resistor to GND, H = 1 k Ω pullup resistor to VCC, NC = Floating.
NC	19	NA	No Connect. Optionally connect 0.1 μ F to GND to reduce noise.

(1) I = Input, O = Output, P = Power, G = Ground

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

		MIN	MAX	UNIT
Supply Voltage Range ⁽³⁾	VCC	- 0.3	4	V
	VDD	- 0.3	1.4	V
Voltage Range	Main Link Input Differential Voltage (IN_Dx)	0	1.56	V
	Main Link Input Single Ended on Pin	- 0.3	1.4	V
	TMDS Output (OUT_Dx)	- 0.3	4	V
	HPD_SRC, VSADJ, SDA_CTL/PRE, OE, A1/EQ2, A0/EQ1, TERM, I2C_EN, SLEW, SCL_CTL/SWAP, SDA_SRC, SCL_SRC	- 0.3	4	V
	HDP_SNK, SDA_SNK, SCL_SNK	- 0.3	6	V
Continuous power dissipation	See # 6.4			
Storage temperature, T _{stg}	- 65	150	°C	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-B.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CC}	Supply Voltage Nominal Value 3.3 V for DP mode	3		3.6	V
	Supply Voltage Nominal Value 3.3 V for HDMI mode	3.13		3.47	V
V _{DD}	Supply Voltage Nominal Value 1.1 V	1		1.27	V
T _J	Junction temperature	0		105	°C
T _A	Operating free-air temperature (TDP158)	0		85	°C
MAIN LINK DIFFERENTIAL PINS					
V _{ID(EYE)}	Peak-to-peak input differential voltage See 图 7-14	75		1200	mV
V _{ID(DC)}	The input differential voltage Peak-to peak DC level, See 图 7-14	200		1200	mV
V _{IC}	Input Common Mode Voltage (Internally Biased)	0.5		0.9	V
d _R	Data rate	0.25		6	Gbps
V _{SADJ}	TMDS compliant swing voltage bias resistor (Nominal 6 k Ω for HDMI and DP combination; 6.49 k Ω for HDMI only) ⁽¹⁾	4.5		8	k Ω
DDC, I2C, HPD, AND CONTROL PINS					
V _{I(DC)}	DC Input Voltage	HDP_SNK, SDA_SNK, SCL_SNK,		5.5	V
		SDA_SRC, SCL_SRC; All other Local I2C, and control pins	- 0.3	3.6	V

6.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{IL}	Low-level input voltage at DDC			0.3 x V _{CC}	V
	Low-level input voltage at HPD			0.8	V
	Low-level input voltage at SDA_CTL/PRE, OE, A1/EQ2, A0/EQ1, TERM, I2C_EN, SLEW, SCL_CTL/SWAP pins only			0.3	V
V _{IM}	Mid-Level input voltage at A1/EQ2, A0/EQ1, TERM, SLEW pins only	1.2		1.6	V
V _{IH}	High-level input voltage at OE, A1/EQ2, A0/EQ1, TERM, I2C_EN, SLEW pins only	0.7 x V _{CC}			V
	High-level input voltage at SDA_SRC, SCL_SRC, SDA_CTL/PRE, SCL_CTL/SWAP	0.7 x V _{CC}			V
	High-level input voltage at SDA_SNK, SCL_SNK	3.2			V
	High-level input voltage at HPD	2			V
V _{OL}	Low-level output voltage			0.4	V
V _{OH}	High-level output voltage	2.4			V
f _{SCL}	SCL clock frequency fast I ² C mode for local I2C control			400	kHz
C _(bus,DDC)	Total capacitive load for each bus line supporting 400 kHz (DDC terminals)			400	pF
C _(bus,I2C)	Total capacitive load for each bus line (local I2C terminals)			100	pF
d _{R(DDC)}	DDC Data rate			400	Kbps
I _{IH}	High level input current	- 30		30	μA
I _{IM}	Mid level input current	- 20		20	μA
I _{IL}	Low level input current	- 10		10	μA
I _{OZ}	High impedance output current			10	μA
R _(OEPu)	Pull up resistance on OE pin	150		250	kΩ

(1) Reducing resistor in V_{SADJ} will increase V_{OD}, care should be taking since resistors below ≈6 kΩ may lead to compliance failures.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TDP158	UNIT
		RSB (WQFN)	
		40 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	3.7	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	23.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	9.9	°C/W
ψ _{JT}	Junction-to-top characterization parameter	0.3	°C/W
ψ _{JB}	Junction-to-board characterization parameter	3.8	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	3.2	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics, Power Supply

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
P _{DI}	Device power Dissipation	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V IN_Dx: VID_PP = 1200 mV, 6 Gbps TMDS pattern, V _I = 3.3 V, I2C_EN = L, SDA_CTL/PRE = L, EQ1/EQ2 = H		200	350	mW
P _{DI2}	Device power Dissipation in DP-Mode	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V IN_Dx: VID_PP = 400 mV, 5.4 Gbps DP pattern, I2C_EN = H, V _{OD} = 400 mV PRE = 0 dB		330	680	mW
P _(STBY1)	Stage 1: Standby Power	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V, HPD = H, No input Signal: Stage 1 See § 10.2			34	mW
	Stage 2: Standby Power	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V, HPD = H, Noise on input Signal: Stage 2 See § 10.2			60	mW
P _(SD1)	Device power in PowerDown	OE = L, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V		8	34	mW
P _(SD2)	Device power in PowerDown in DP-Mode	OE = L, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V		8	34	mW
I _{CC1}	V _{CC} Supply current	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V IN_Dx: VID_PP = 1200 mV, 6 Gbps TMDS pattern I2C_EN = L, SDA_CTL/PRE = L, EQ1/EQ2 = H,		8	20	mA
I _{CC2}	V _{CC} Supply current in DP-Mode	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V IN_Dx: VID_PP = 400 mV, 5.4 Gbps DP pattern, I2C_EN = H, V _{OD} = 400 mV PRE = 0 dB		45	110	mA
I _{DD1}	V _{DD} Supply current	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V IN_Dx: VID_PP = 1200 mV, 6 Gbps TMDS pattern I2C_EN = L, SDA_CTL/PRE = L, EQ1/EQ2 = H		160	220	mA
I _{DD2}	V _{DD} Supply current DP-Mode	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V IN_Dx: VID_PP = 400 mV, 5.4 Gbps DP pattern, I2C_EN = H, V _{OD} = 40 mV PRE = dB		160	220	mA
I _(STBY1)	Stage 1: Standby current See § 10.2	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V, HPD = H: No signal on IN_CLK	3.3 V Rail		7	mA
			1.1 V Rail		7	mA
	Stage 2: Standby current See § 10.2	OE = H, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V, HPD = H: No valid signal on IN_CLK	3.3 V Rail		7	mA
			1.1 V Rail		27	mA
I _(SD11)	PowerDown current - HDMI Mode	OE = L, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V, or OE = H, HPD = L	3.3 V Rail	1	7	mA
			1.1 V Rail	4	7	mA
I _(SD2)	PowerDown current in DP-Mode	OE = L, V _{CC} = 3.3 V/3.6 V, V _{DD} = 1.1 V/1.27 V	3.3 V Rail	1	7	mA
			1.1 V Rail	4	7	mA

(1) The maximum rating is simulated at 3.6 V V_{CC} and 1.27 V V_{DD} and at 85°C temperature unless otherwise noted.

(2) The typical rating is simulated at 3.3 V V_{CC} and 1.1 V V_{DD} and at 27°C temperature unless otherwise noted.

6.6 Electrical Characteristics, Differential Input

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
$D_{R(RX_DATA)}$	TMDS data lanes data rate		0.25		6	Gbps
$D_{R(RX_CLK)}$	TMDS clock lanes clock rate		25		340	Mhz
t_{RX_DUTY}	Input clock duty circle		40%	50%	60%	
$R_{(INT)}$	Input differential termination impedance		80	100	120	Ω
$V_{(TERM)}$	Input Common Mode Voltage	OE = H		0.7		V

(1) The maximum rating is simulated at 3.6 V V_{CC} and 1.27 V V_{DD} and at 85°C temperature unless otherwise noted.

(2) The typical rating is simulated at 3.3 V V_{CC} and 1.1 V V_{DD} and at 27°C temperature unless otherwise noted.

6.7 Electrical Characteristics, TMDS Differential Output

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
$V_{OD(PP)}$	Output differential voltage before pre-emphasis; See § 8.3.11	$V_{SADJ} = 6\text{ k}\Omega$; SDA_CTL/PRE = H; See 图 7-4	600		1400	mV
$V_{OD(SS)}$	Steady state output differential voltage See § 8.3.11	$V_{SADJ} = 6\text{ k}\Omega$; SDA_CTL/PRE = H, See 图 7-4	350		720	mV
		$V_{SADJ} = 5.5\text{ k}\Omega$; SDA_CTL/PRE = L, See 图 7-3	350		1000	mV
I_{OS}	Short circuit current limit	Main link output shorted to GND			50	mA
$R_{(TERM)}$	Source Termination resistance for HDMI 2.0		75		150	Ω

6.8 Electrical Characteristics, DDC, I2C, HPD, and ARC

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
DDC and I2C						
V_{IL}	SCL/SDA_CTL, SCL/SDA_SRC low level input voltage				$0.3 \times V_{CC}$	V
V_{IH}	SCL/SDA_CTL, input voltage		$0.7 \times V_{CC}$		$V_{CC} + 0.5$	V
V_{OL}	SCL/SDA_CTL, SCL/SDA_SRC low level output voltage	$I_O = 3\text{ mA}$ and $V_{CC} > 2\text{ V}$			0.4	V
		$I_O = 3\text{ mA}$ and $V_{CC} > 2\text{ V}$			$0.2 \times V_{CC}$	V
HPD						
V_{IH}	High-level input voltage	HPD_SNK	2.1			V
V_{IL}	Low-level input voltage	HPD_SNK			0.8	V
V_{OH}	High-level output voltage	$I_{OH} = -500\text{ }\mu\text{A}$; HPD_SRC,	2.4		3.6	V
V_{OL}	Low-level output voltage	$I_{OL} = 500\text{ }\mu\text{A}$; HPD_SRC,	0		0.4	V
I_{LKG}	Failsafe condition leakage current	$V_{CC} = 0\text{ V}$; $V_{DD} = 0\text{ V}$; HPD_SNK = 5 V;			40	$\mu\text{ A}$
$I_{H(HPD)}$	High level input current	Device powered; $V_{IH} = 5\text{ V}$; $I_{H(HPD)}$ includes $R_{(pdHPD)}$ resistor current			40	$\mu\text{ A}$
		Device powered; $V_{IL} = 0.8\text{ V}$; $I_{L(HPD)}$ includes $R_{(pdHPD)}$ resistor current			30	$\mu\text{ A}$
$R_{(pdHPD)}$	HPD input termination to GND	$V_{CC} = 0\text{ V}$	150	190	220	$\text{k}\Omega$

(1) The maximum rating is simulated at 3.6 V V_{CC} and 1.27 V V_{DD} and at 85°C temperature unless otherwise noted.

(2) The typical rating is simulated at 3.3 V V_{CC} and 1.1 V V_{DD} and at 27°C temperature unless otherwise noted.

6.9 Electrical Characteristics, TMDS Differential Output in DP-Mode

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX ⁽¹⁾	UNIT
$V_{(TX_DIFFPP_LVL0)}$	Differential peak-to-peak output voltage level 0	Based on default state of V0_P0_VOD register		415		V
$V_{(TX_DIFFPP_LVL1)}$	Differential peak-to-peak output voltage level 1	Based on default state of V1_P0_VOD register		660		V
$V_{(TX_DIFFPP_LVL2)}$	Differential peak-to-peak output voltage level 2	Based on default state of V2_P0_VOD register		880		V
$\Delta V_{OD(L0L1)}$	Output peak-to-peak differential voltage delta	$\Delta V_{ODn} = 20 \times \log(V_{ODL(n+1)} / V_{ODL(n)})$ measured in compliance with latest PHY CTS 1.2	1		6	dB
$\Delta V_{OD(L1L2)}$			1		5	dB
$V_{(TX_PRE_RATIO_0)}$	Pre-emphasis level 0	RBR, HBR and HBR2		0		dB
$V_{(TX_PRE_RATIO_1)}$	Pre-emphasis level 1	RBR, HBR and HBR2	2		4.2	dB
$V_{(TX_PRE_RATIO_2)}$	Pre-emphasis level 2	RBR, HBR and HBR2	5		7.2	dB
$\Delta V_{PRE(L1L0)}$	Pre-emphasis delta	Measured in compliance with latest PHY CTS 1.2	2			dB
$\Delta V_{PRE(L2L1)}$			1.6			dB

(1) Does not support Level 3 swing or pre-emphasis.

6.10 Switching Characteristics, TMDS

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
d_R	Data rate		250		6000	Mbps
$t_{T(DATA)}$	Transition time (rise and fall time); measured at 20% and 80%. SDA_CTL = L, OE = H, All Data Rates Note: Data lane control by I2C only: See § 8.3.10	Reg0Ah[1:0] = 11 (default)		60		ps
		Reg0Ah[1:0] = 10		80		ps
		Reg0Ah[1:0] = 01		95		ps
		Reg0Ah[1:0] = 00		110		ps
$t_{T(CLOCK)}$	Note: Data lane control by I2C only: See § 8.3.10	TERM = H; Reg0Bh[7:6] = 11		122		ps
		Reg0Bh[7:6] = 10		150		ps
		TERM = L; Reg0Bh[7:6] = 00		180		ps
		TERM = NC; Reg0Bh[7:6] = 01		203		ps

(1) The maximum rating is simulated at 3.6 V V_{CC} and 1.27 V V_{DD} and at 85°C temperature unless otherwise noted.

(2) The typical rating is simulated at 3.3 V V_{CC} and 1.1 V V_{DD} and at 27°C temperature unless otherwise noted.

6.11 Switching Characteristics, HPD

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
$t_{PD(HPD)}$	Propagation delay from HPD_SNK to HPD_SRC; rising edge and falling edge	see 图 7-8 ; not valid during switching time		40	120	ns
$t_{T(HPD)}$	HPD logical disconnected timeout	see 图 7-9	2			ms

(1) The Maximum rating is simulated at 3.6 V V_{CC} and 1.27 V V_{DD} and at 85°C temperature unless otherwise noted

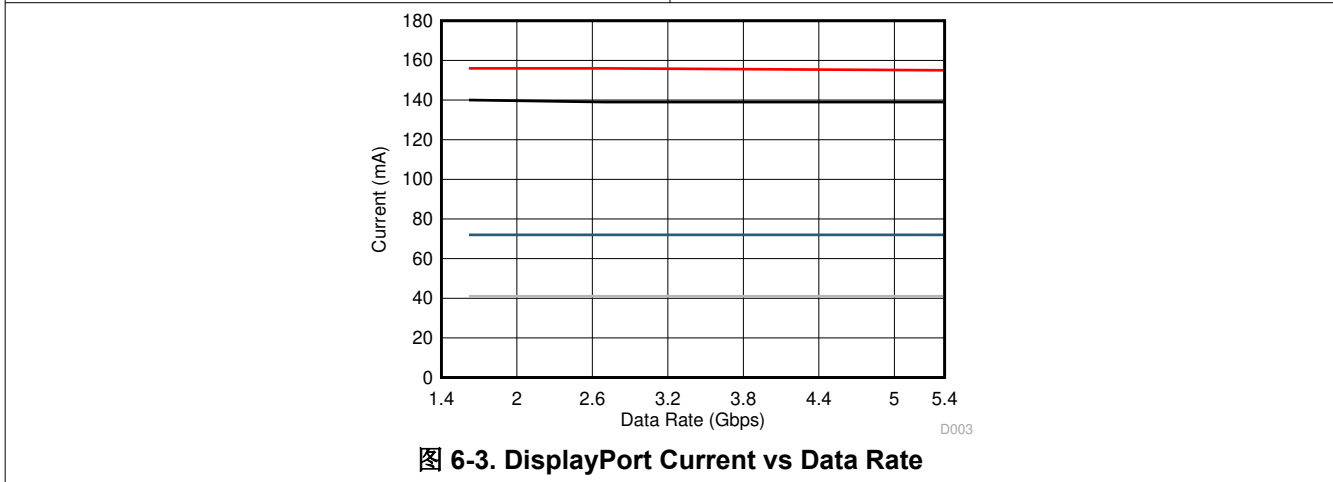
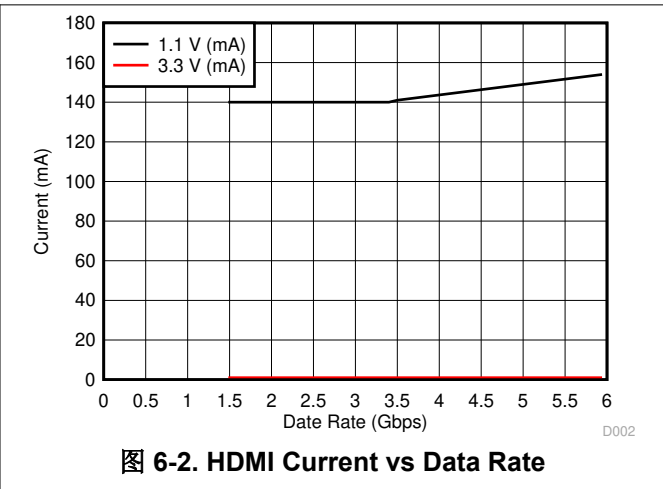
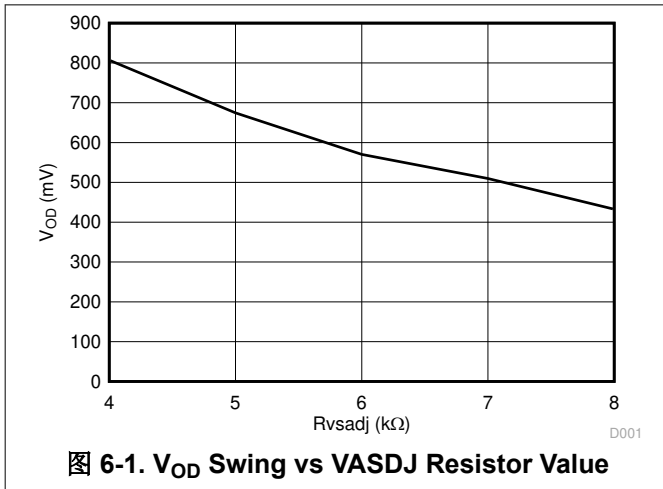
(2) The Typical rating is simulated at 3.3 V V_{CC} and 1.1 V V_{DD} and at 27°C temperature unless otherwise noted

6.12 Switching Characteristics, DDC and I²C

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_r	Rise time of both SDA and SCL signals	$V_{CC} = 3.3\text{ V}$; See 图 7-12			300	ns
t_f	Fall time of both SDA and SCL signals	See 图 7-12			300	ns
t_{HIGH}	Pulse duration , SCL high	See 图 7-11	0.6			$\mu\text{ s}$
t_{LOW}	Pulse duration , SCL low	See 图 7-11	1.3			$\mu\text{ s}$
t_{SU1}	Setup time, SDA to SCL	See 图 7-11	100			ns
$t_{ST, STA}$	Setup time, SCL to start condition	See 图 7-11	0.6			$\mu\text{ s}$
$t_{HD, STA}$	Hold time, start condition to SCL	See 图 7-10	0.6			$\mu\text{ s}$
$t_{HD, DAT}$	Data Hold Time		0			ns
$t_{VD, DAT}$	Data valid time		0.9			$\mu\text{ s}$
$t_{VD, ACK}$	Data valid acknowledge time		0.9			$\mu\text{ s}$
$t_{ST, STO}$	Setup time, SCL to stop condition	See 图 7-10	0.6			$\mu\text{ s}$
$t_{(BUF)}$	Bus free time between stop and start condition	See 图 7-10	1.3			$\mu\text{ s}$

6.13 Typical Characteristics



7 Parameter Measurement Information

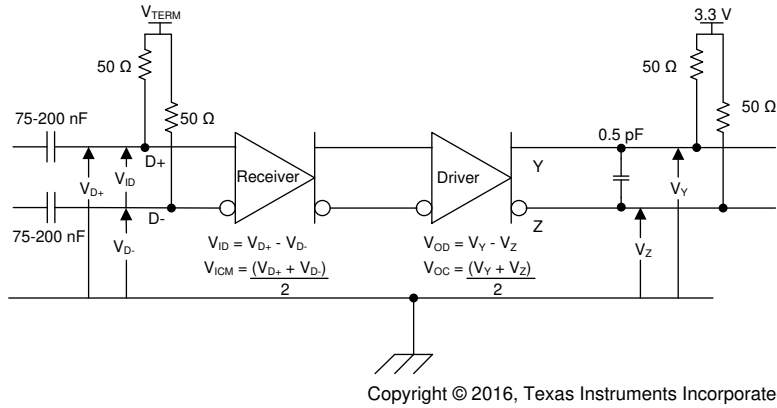


图 7-1. TMD5 Main Link Test Circuit

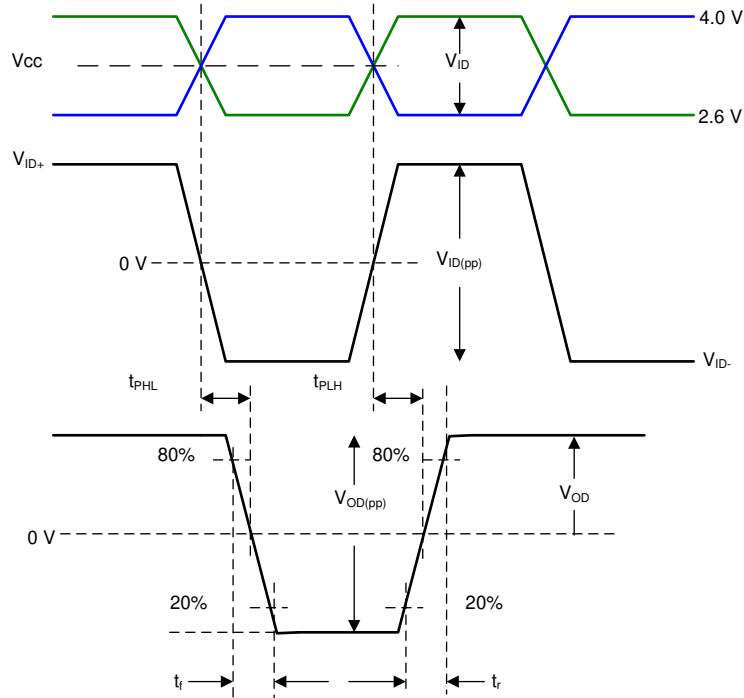


图 7-2. Input or Output Timing Measurements

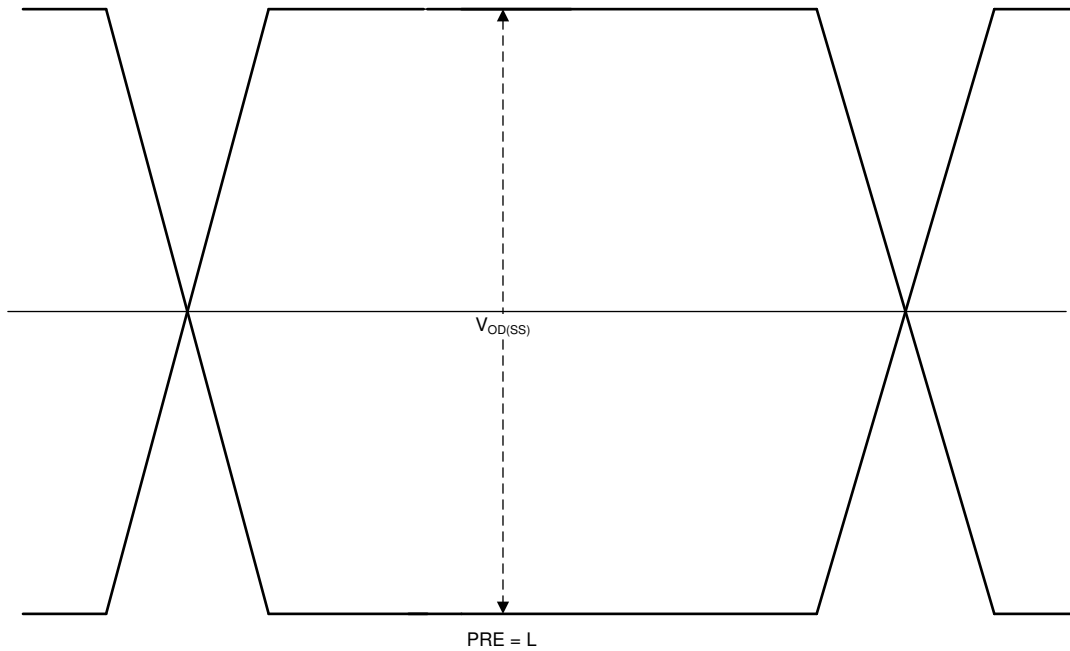


图 7-3. Output Differential Waveform

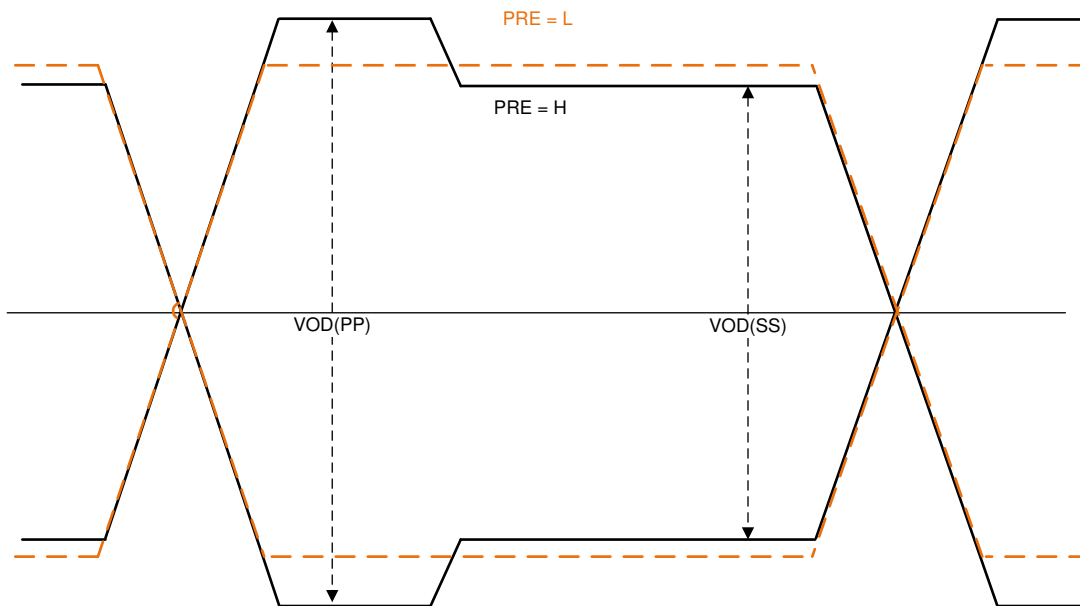
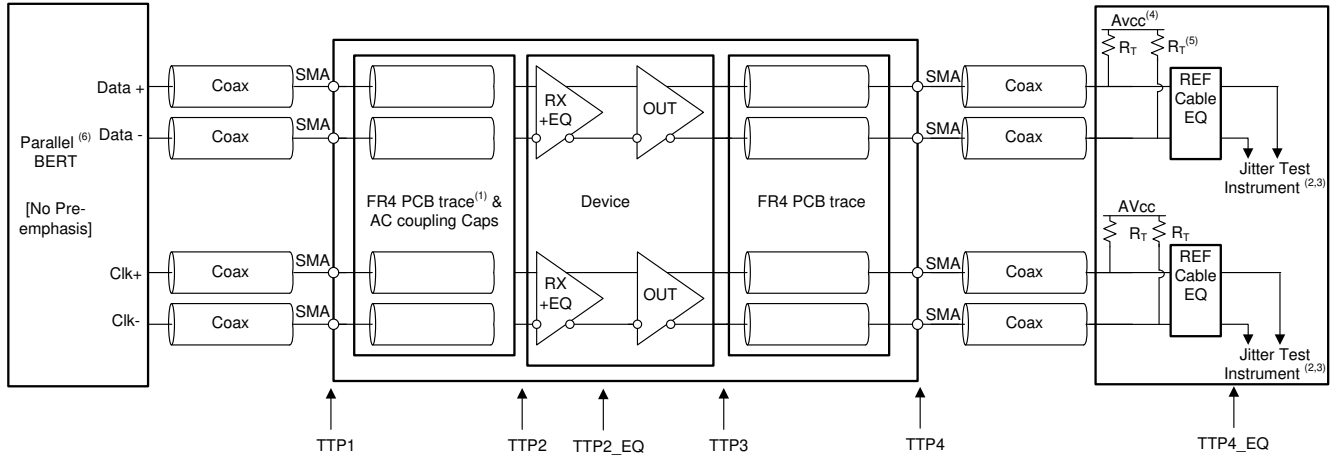


图 7-4. Output Differential Waveform with De-Emphasis



Copyright © 2016, Texas Instruments Incorporated

- A. The FR4 trace between TTP1 and TTP2 is designed to emulate 1-8” of FR4, AC coupling cap, connector and another 1-8” of FR4. Trace width - 4 mils. 100 Ω differential impedance.
- B. All Jitter is measured at a BER of 10⁹
- C. Residual jitter reflects the total jitter measured at TTP4 minus the jitter measured at TTP
- D. AVCC = 3.3 V
- E. R_T = 50 Ω
- F. The input signal from parallel Bert does not have any pre-emphasis. Refer to *Recommended Operating Conditions*.

图 7-5. HDMI Output Jitter Measurement

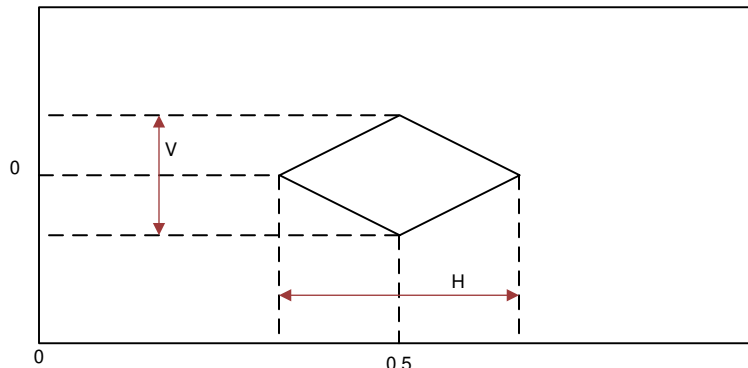


图 7-6. Output Eye Mask at TTP4_EQ for HDMI 2.0

TMDS Data Rate (Gbps)	H (Tbit)	V (mV)
3.4 < DR < 3.712	0.6	335
3.712 < DR < 5.94	$- 0.0332R_{bit}^2 + 0.2312 R_{bit} + 0.1998$	$- 19.66R_{bit}^2 + 106.74R_{bit} + 209.58$
5.94 ≤ DR ≤ 6.0	0.4	150

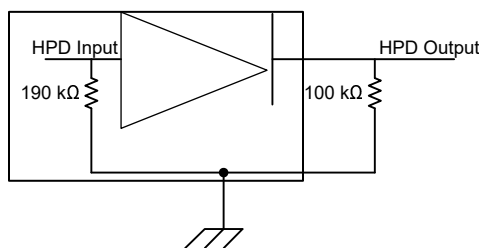


图 7-7. HPD Test Circuit

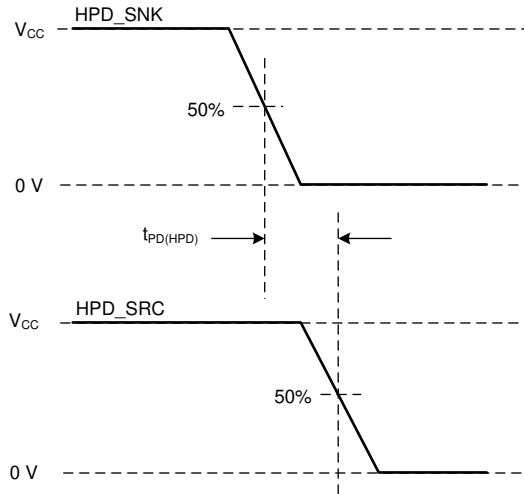


图 7-8. HPD Timing Diagram No. 1

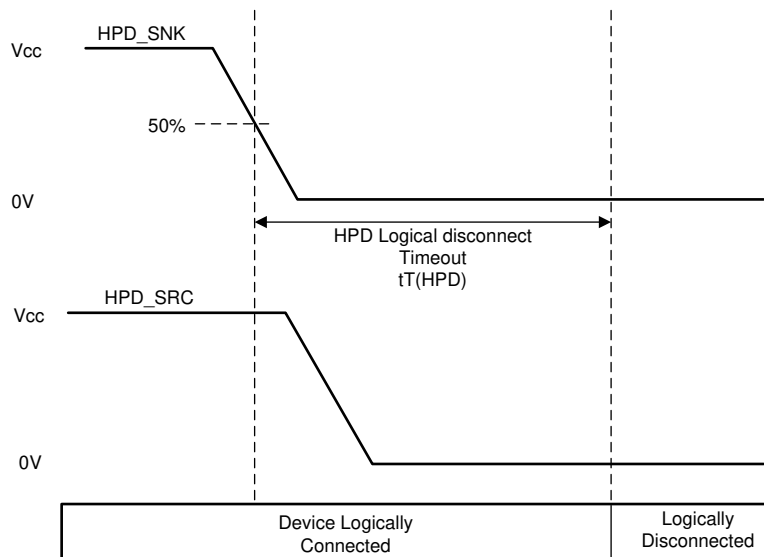


图 7-9. HPD Logic Disconnect Timeout

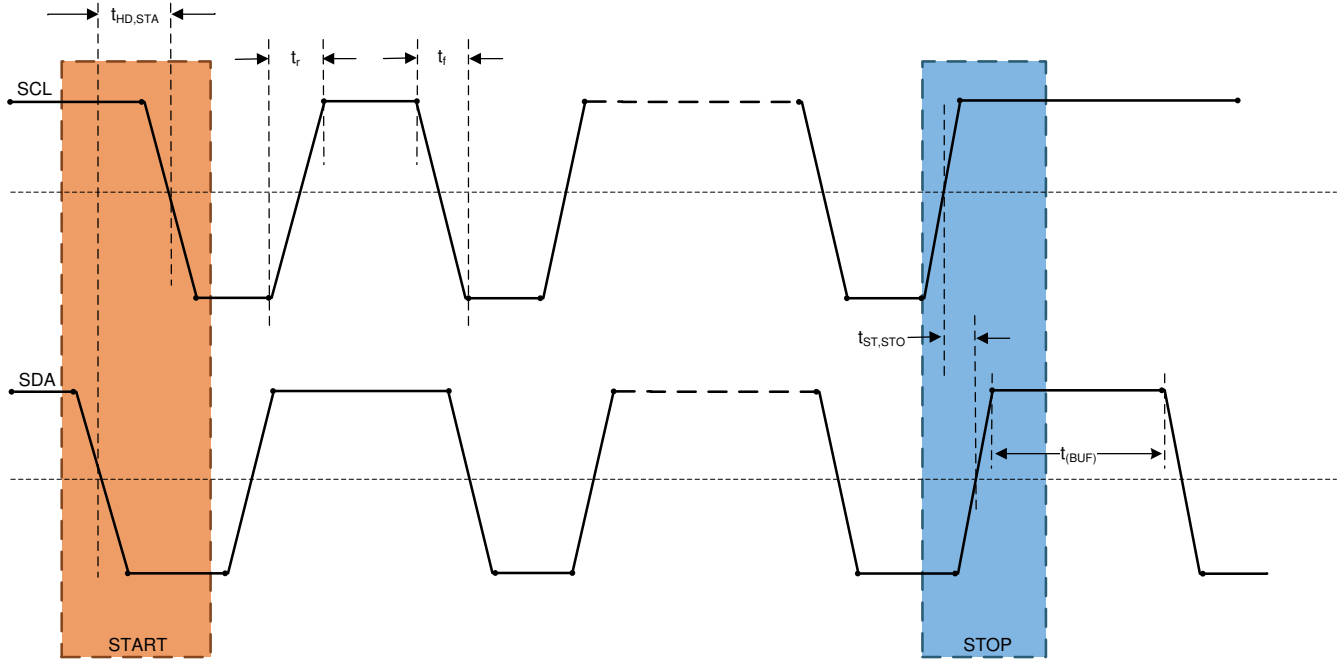


图 7-10. Start and Stop Condition Timing

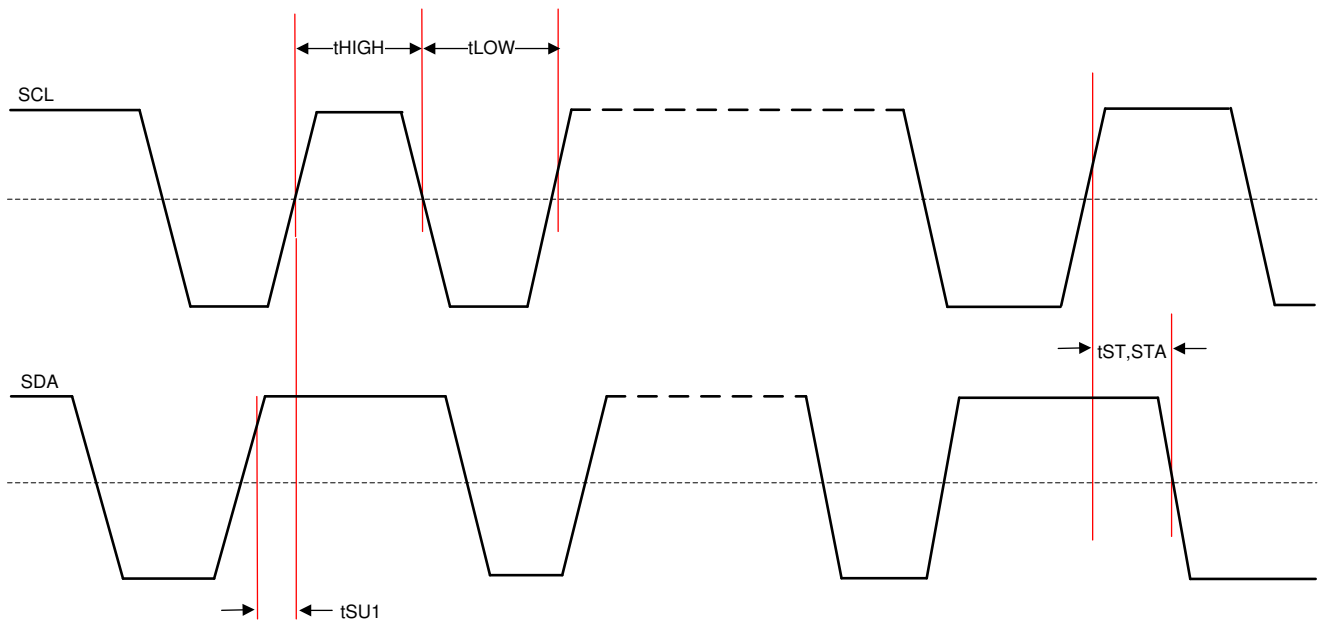


图 7-11. SCL and SDA Timing

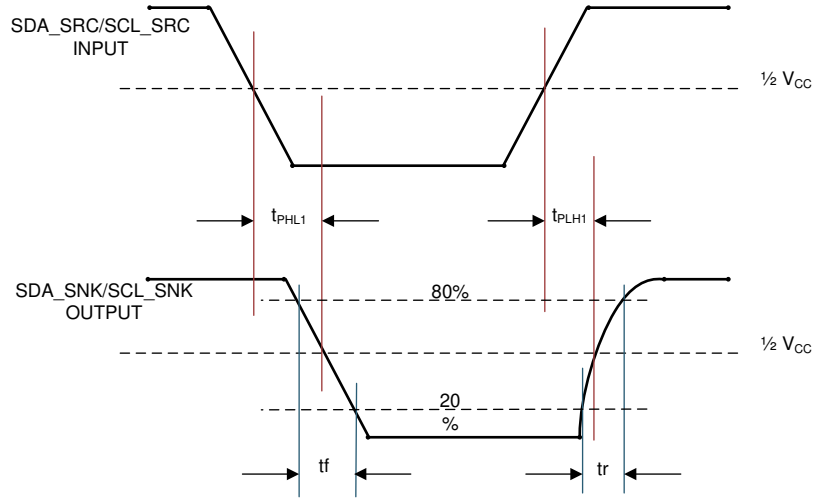


图 7-12. DDC Propagation Delay - Source to Sink

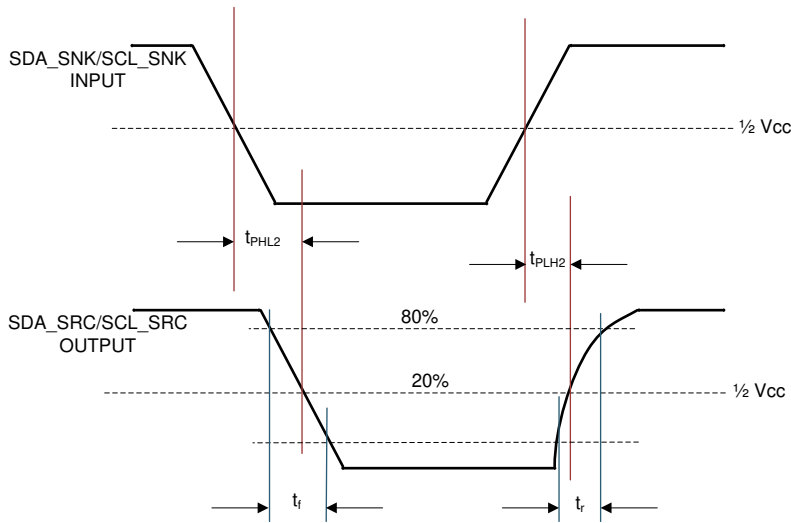


图 7-13. DDC Propagation Delay - Sink to Source

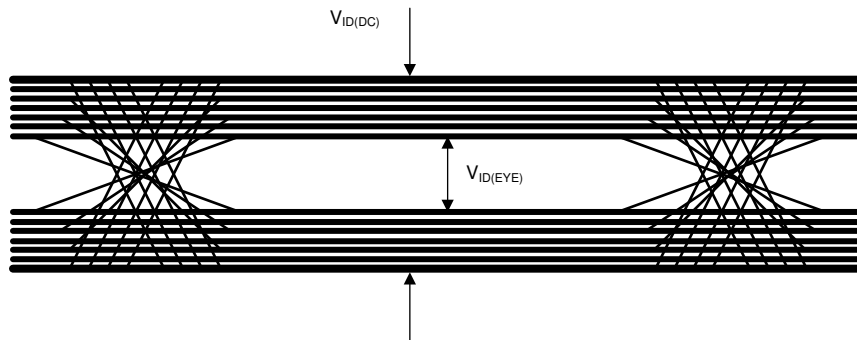


图 7-14. $V_{ID(DC)}$ and $V_{ID(EYE)}$

8 Detailed Description

8.1 Overview

The TDP158 is an AC-coupled digital video interface (DVI) or high-definition multimedia interface (HDMI) signal input to Transition Minimized Differential Signal (TMDS) level shifting Redriver. The TDP158 supports four TMDS channels, Hot Plug Detect, and a Digital Display Control (DDC) interfaces. The TDP158 supports signaling rates up to 6 Gbps to allow for the highest resolutions of 4k2k60p 24 bits per pixel and up to WUXGA 16-bit color depth or 1080p with higher refresh rates. For passing compliance and reducing system level design issues, several features have been included such as TMDS output amplitude adjust using an external resistor on the VSADJ pin, source termination selection, pre-emphasis, and output slew rate control. Device operation and configuration can be programmed by pin strapping or I²C. Four TDP158 devices can be used on one I²C bus when I2C_EN is high with device address set by A0/A1.

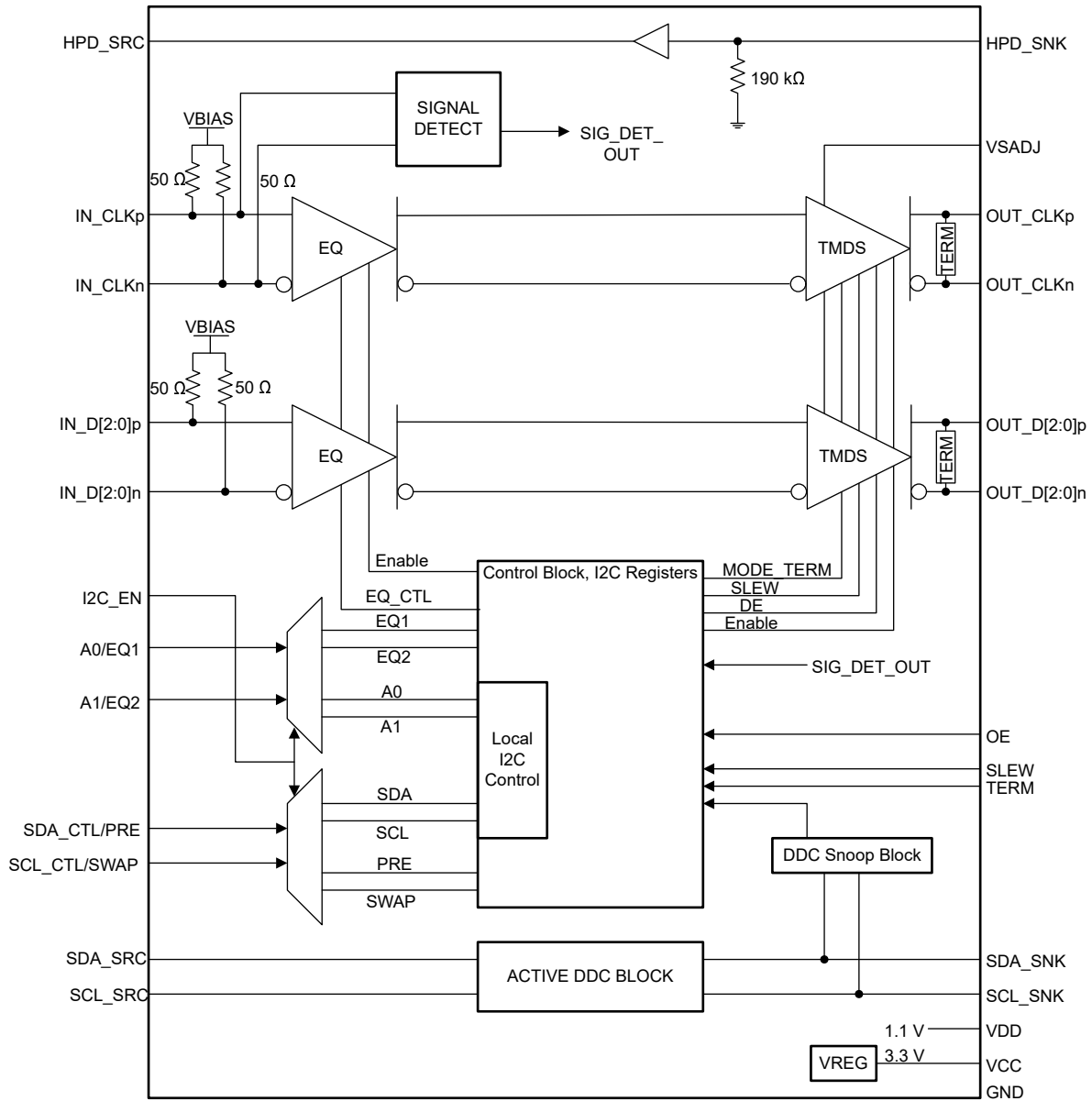
To reduce active power the TDP158 supports dual power supply rails of 1.1 V on VDD and 3.3 V on VCC. There are several methods of power management such as going into power down mode using three methods:

1. HPD is low
2. Writing a 1 to register 09h[3]
3. De-asserting OE

De-asserting OE clears the I²C registers, thus once re-asserted, the device must be reprogrammed if I²C was used for device setup. The TDP158 requires the source to write a 1 to the TMDS_CLOCK_RATIO_STATUS register for the TDP158 to resume 75 Ω to 150 Ω source termination upon return to normal active operation from re-asserted, OE, or re-asserted HPD. If this bit is already set as a one during the source to sink read, then the TDP158 automatically sets this bit to 1. The SIG_EN register enables the signal detect circuit that provides an automatic power-management feature during normal operation. When no valid signal is present on the clock input, the device enters Standby mode. DDC link supports the HDMI 2.0b SCDC communication, 100 Kbps data rate default and 400 Kbps adjustable by software.

TDP158 supports fixed EQ gain control to compensate for different lengths of input cables or board traces. The EQ gain can be software adjusted by I²C control or pin strapping EQ1 and EQ2 pins. Customers can use the TERM to change to one of three source termination impedances for better output performance when working in HDMI 1.4b or HDMI 2.0b. When the TMDS_CLOCK_RATIO_STATUS bit is set to 1, the TDP158 automatically switches in 75 Ω to 150 Ω source termination. To assist in ease of implementation, the TDP158 supports lanes swapping, see [# 8.3.3](#). The device's available extended commercial temperature range is 0°C to 85°C.

8.2 Functional Block Diagram

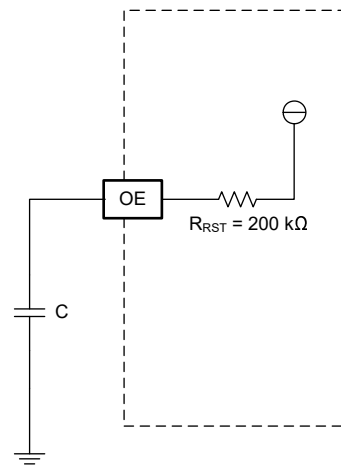


Copyright © 2016, Texas Instruments Incorporated

8.3 Feature Description

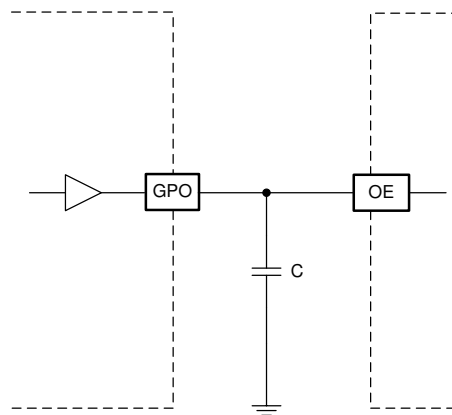
8.3.1 Reset Implementation

When OE is low, control signal inputs are ignored; the HDMI inputs and outputs are high impedance. It is critical to transition the OE from a low level to high after the V_{CC} supply has reached the minimum recommended operating voltage. This is achieved by a control signal to the OE input, or by an external capacitor connected between OE and GND. To ensure the TDP158 is properly reset, the OE pin must be de-asserted for at least 100 μ s before being asserted. When OE is re-asserted the TDP158 must be reprogrammed if it was programmed by I²C and not pin strapping. When implementing the external capacitor, the size of the external capacitor depends on the power up ramp of the V_{CC} supply, where a slower ramp-up results in a larger value external capacitor. Refer to the latest reference schematic for TDP158; consider approximately 0.1 μ F capacitor as a reasonable first estimate for the size of the external capacitor. Both OE implementations are shown in [Figure 8-1](#) and [Figure 8-2](#).



Copyright © 2016, Texas Instruments Incorporated

图 8-1. External Capacitor Controlled OE



Copyright © 2016, Texas Instruments Incorporated

图 8-2. OE Input from Active Controller

8.3.2 Operation Timing

TDP158 starts to operate after the OE signal is properly set after power up timing is complete. See 图 8-3 and 表 8-1. Keeping OE low until V_{DD} and V_{CC} becomes stable avoids any timing requirements as shown in 图 8-3.

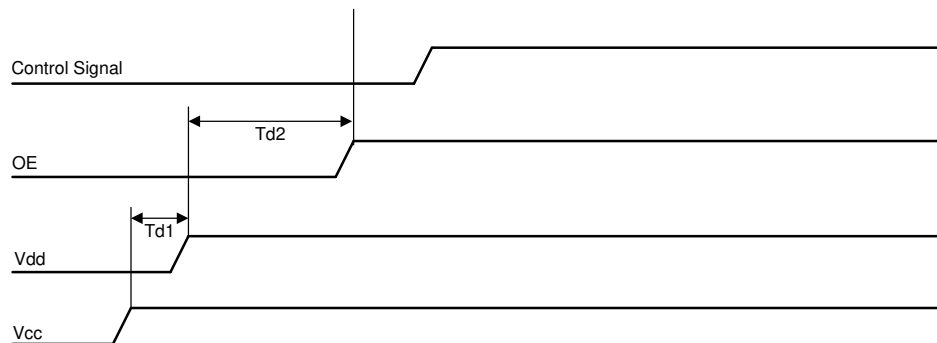


图 8-3. Power Up Timing for TDP158

表 8-1. Power Up and Operation Timing Requirements

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
t_{d1}	V_{CC} stable before V_{DD}	0		200	μ s
t_{d1}	V_{DD} and V_{CC} stable before OE de-assertion	100			μ s
$V_{DD(ramp)}$	V_{DD} supply ramp up requirements	0.2		100	ms
$V_{CC(ramp)}$	V_{CC} supply ramp up requirements	0.2		100	ms

8.3.3 Lane Control

The TDP158 has various lane control features. By default the high speed lanes are globally controlled. Pin strapping can globally control features like receiver equalization, V_{OD} swing and pre-emphasis. I²C programming performs the same global programming using default configurations. Through I2C a method to control receive equalization, transmitter swing (V_{OD}) and pre-emphasis on each individual lane. Setting reg09h[5] = 1 puts the device into independent lane configuration mode.

Reg31h[7:3] controls the clock lane, reg32h[7:3] controls lane D0, reg33h[7:3] controls lane D1 and reg34h[7:3] controls lane D2 while Reg4E and Reg4F control the individual lane EQ control.

备注

If the swap function is enabled and individual lane control has been implemented, then it is recommended to reprogram the lanes to make sure they match the expected results. Registers are mapped to the pin name convention.

8.3.4 Swap

TDP158 incorporates a swap function which can swap the lanes, see 图 8-4. The EQ, Pre-emphasis, termination, and slew setup will follow the new mapping. This function can be used with the SCL_CTL/SWAP pin 13 when I2C_EN pin 8 is low or can be implemented using control the register 0x09h bit 7 and is only valid for HDMI mode.

表 8-2. Swap Functions

Normal Operation	SWAP = L or CSR 0x09h bit 7 is 1' b1	Pin Numbers
IN_D2 → OUT_D2	IN_CLK → OUT_CLK	[1, 2] → [30, 29]
IN_D1 → OUT_D1	IN_D0 → OUT_D0	[4, 5] → [27, 26]
IN_D0 → OUT_D0	IN_D1 → OUT_D1	[6, 7] → [25, 24]
IN_CLK → OUT_CLK	IN_D2 → OUT_D2	[9, 10] → [22, 21]

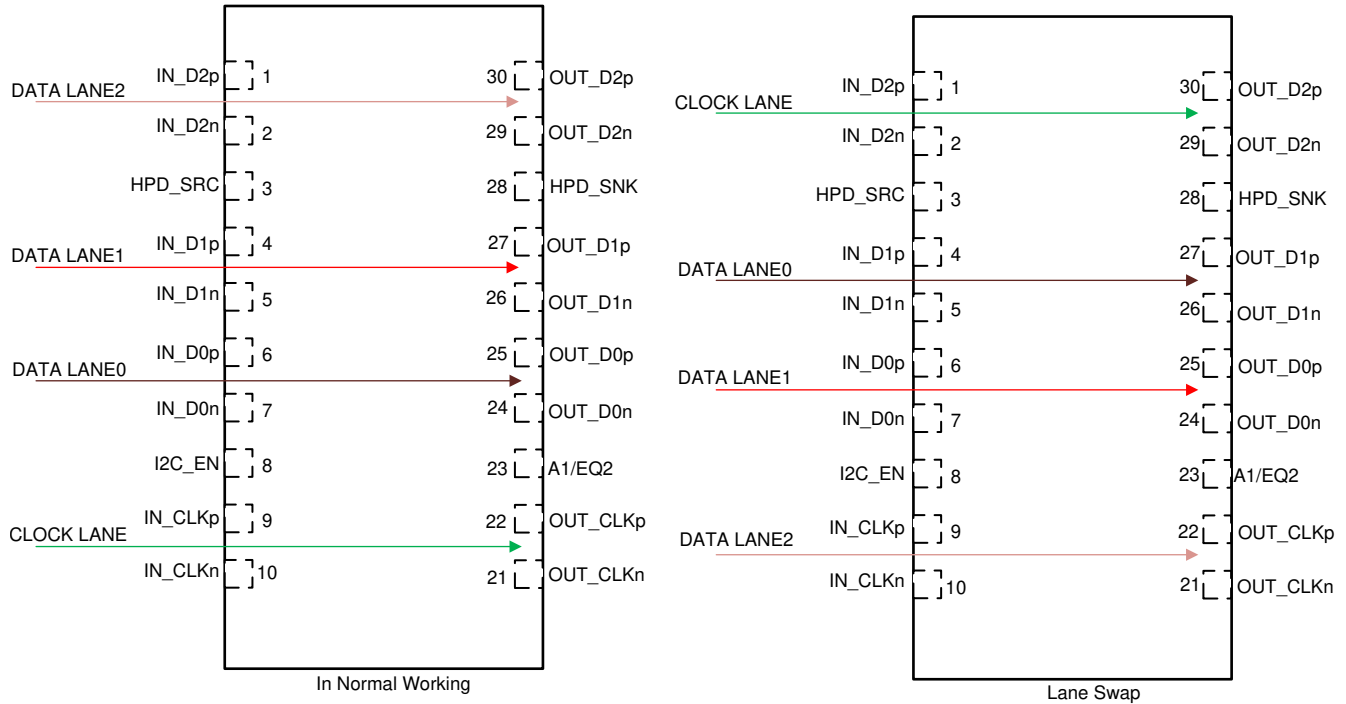


图 8-4. TDP158 Swap Function

8.3.5 Main Link Inputs

Standard Dual Mode DisplayPort terminations are integrated on all inputs with expected AC coupling capacitors on board prior to input pins. External terminations are not required. Each input data channel contains an equalizer to compensate for cable or board losses. The voltage at the input pins must be limited under the absolute maximum ratings.

8.3.6 Receiver Equalizer

The equalizer is used to clean up inter-symbol interference (ISI) jitter/loss from the bandwidth-limited board traces or cables. TDP158 supports fixed receiver equalizer by setting the A0/EQ1 and A1/EQ2 pins or through I²C. 表 8-3 shows the pin strap settings and EQ values.

表 8-3. Receiver EQ Programming and Values

RX EQ (dB)	Global		Independent Lane Control			
	Pin Control ⁽¹⁾	I2C Control	I2C Control ⁽²⁾			
	{EQ2,EQ1}	P0_Reg0D[6:3]	D2 P0_Reg4E[3:0]	D1 P0_Reg4E[7:4]	D3 P0_Reg4F[3:0]	CLK ^{(2) (3)} P0_Reg4F[7:4]
2	2' b00	4' b0000	4' b0000	4' b0000	4' b0000	4' b0000
3	2' b0Z	4' b0001	4' b0001	4' b0001	4' b0001	4' b0001
4		4' b0010	4' b0010	4' b0010	4' b0010	4' b0010
5	2' b01	4' b0011	4' b0011	4' b0011	4' b0011	4' b0011
6.5	2' bZ0	4' b0100	4' b0100	4' b0100	4' b0100	4' b0100
7.5		4' b0101	4' b0101	4' b0101	4' b0101	4' b0101
8.5	2' bZZ	4' b0110	4' b0110	4' b0110	4' b0110	4' b0110
9		4' b0111	4' b0111	4' b0111	4' b0111	4' b0111
10	2' bZ1	4' b1000	4' b1000	4' b1000	4' b1000	4' b1000
11	2' b10	4' b1001	4' b1001	4' b1001	4' b1001	4' b1001
12		4' b1010	4' b1010	4' b1010	4' b1010	4' b1010
13		4' b1011	4' b1011	4' b1011	4' b1011	4' b1011
14		4' b1100	4' b1100	4' b1100	4' b1100	4' b1100

表 8-3. Receiver EQ Programming and Values (continued)

RX EQ (dB)	Global		Independent Lane Control			
	Pin Control ⁽¹⁾	I2C Control	I2C Control ⁽²⁾			
	{EQ2,EQ1}	P0_Reg0D[6:3]	D2 P0_Reg4E[3:0]	D1 P0_Reg4E[7:4]	D3 P0_Reg4F[3:0]	CLK ^{(2) (3)} P0_Reg4F[7:4]
14.5	2' b1Z	4' b1101	4' b1101	4' b1101	4' b1101	4' b1101
15		4' b1110	4' b1110	4' b1110	4' b1110	4' b1110
15.5	2' b11	4' b1111	4' b1111	4' b1111	4' b1111	4' b1111

(1) For Pin Control 0 = 1 k Ω pulldown resistor to GND, 1 = 1 k Ω pullup resistor to VCC, Z = Floating (No Connect)

(2) Individual Lane control is based upon the pin names with no swap

(3) The CLK EQ in HDMI mode is controlled by register P0_Reg0D[2:1]

8.3.7 Input Signal Detect Block

When SIG_EN is enabled through I²C the receiver looks for a valid HDMI clock signal input and is fully functional when a valid signal is detected. If no valid HDMI clock signal is detected, then the device enters standby mode waiting for a valid signal at the clock input. All of the TMDS outputs and IN_D[0:2] are in high-Z status. HDMI signal detect circuit is default enabled. If there is a loss of signal, then reg20h[5] can be read to determine if the TDP158 has detected a valid signal or not.

8.3.8 Transmitter Impedance Control

HDMI 2.0 standard requires a source termination impedance in the 75 Ω to 150 Ω range for data rates > 3.4 Gbps. HDMI 1.4b requires no source termination but has a provision for using 150 Ω to 300 Ω for higher data rates. The TDP158 has three termination levels that are selectable using pin 16 when programming through pin strapping or when using I²C programming through reg0Bh[4:3]. When the TMDS_CLOCK_RATIO_STATUS bit, reg0Bh[1] = 1 the TDP158 automatically turns on the 75 Ω to 150 Ω source termination otherwise the termination must be selected. See 表 8-4.

表 8-4. Source Termination Control Table

Pin 16	Reg0Bh[4:3]	Source Termination
TERM = L	00	150 Ω \cong 300 Ω
TERM = NC	01	None
	10	Automatic set based upon TMDS_CLOCK_RATIO_STATUS bit
TERM = H	11	75 Ω \cong 150 Ω

备注

If the TMDS_CLOCK_RATIO_STATUS bit = 1, then the TDP158 automatically switches in 75 Ω \cong 150 Ω termination.

8.3.9 TMDS Outputs

A 1% precision resistor, connected from VSADJ pin to ground is recommended to allow the differential output swing to comply with TMDS signal levels. The differential output driver provides a typical 10-mA current sink capability, which provides a typical 500-mV voltage drop across a 50- Ω termination resistor.

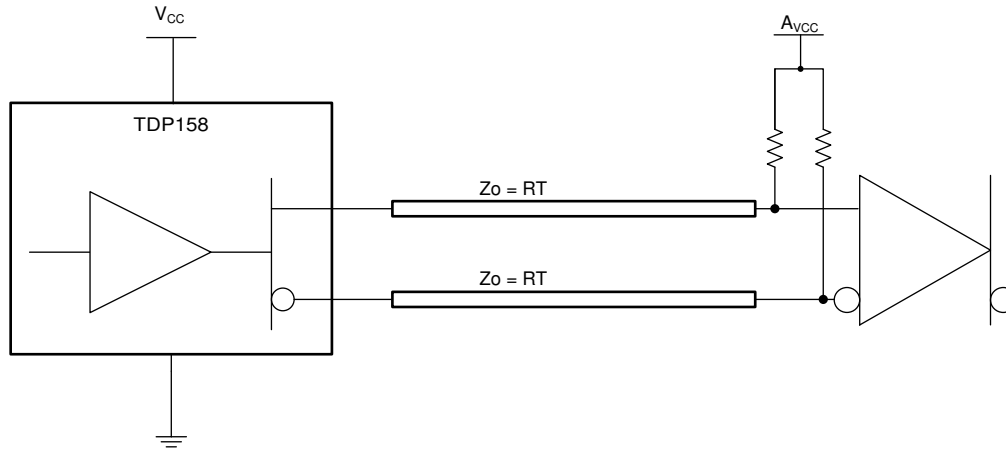


图 8-5. TMDS Driver and Termination Circuit

Referring to [图 8-5](#), if V_{CC} (TDP158 supply) and A_{VCC} (sink termination supply) are both powered, the TMDS output signals are high impedance when $OE = low$. Both supplies being active is the normal operating condition. A total of approximately 33-mW of power is consumed by the terminations independent of the OE logical selection. When A_{VCC} is powered on, normal operation (OE controls output impedance) is resumed. When the power source of the device is off and the power source to termination is on, the $I_{O(off)}$, output leakage current, specification ensures the leakage current is limited 45- μA or less. The clock and data lanes V_{OD} can be changed through I²C reg0Ch[7:2], $VSWING_DATA$ and $VSWING_CLK$.

8.3.10 Slew Rate Control

As the clock signal tends to be a primary source of EMI, the TDP158 provides the ability to slow down the TMDS output edge rates. There are two ways of changing the slew rate, Pin strapping for clock lane and I²C for both clock and data lanes. Refer to [节 6.10](#)

8.3.11 Pre-Emphasis

The TDP158 provides pre-emphasis on the data lanes allowing the output signal pre-conditioning to offset interconnect losses between the TDP158 outputs and a TMDS receiver. Pre-emphasis is not implemented on the clock lane unless the TDP158 is in DP mode; at which time, it becomes a data lane. The default value for pre-emphasis is 0 dB. There are two methods to implement pre-emphasis, pin strapping or through I²C programming. When using pin strapping, the SDA_CTL/PRE pin controls global pre-emphasis values of 0 dB or 3.5 dB. Through I²C, reg0Ch[1:0] pre-emphasis values are 0 dB, 3.5 dB, and 6 dB. The 6 dB value has different meanings when the device is in normal operational mode (reg09h[5] = 0) or when the TDP158 has been put into DP-mode (reg09h[5] = 1). As 图 8-6 shows, the 6 dB pre-emphasis setting will result in an output of 3 dB of pre-emphasis with 3 dB of de-emphasis when device is in normal HDMI operation. As 图 8-7 shows, the output will be about 5 dB pre-emphasis with a 1 dB de-emphasis when selecting 6 dB pre-emphasis setting for DP-mode. $V_{OD(PP)}$ value will not go above 1 V.

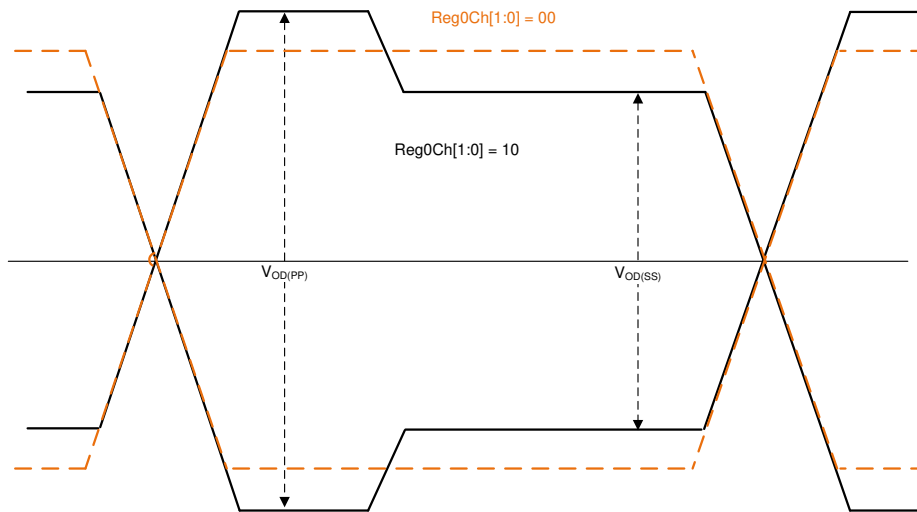


图 8-6. 6 dB Pre-Emphasis Setting in Normal Operation

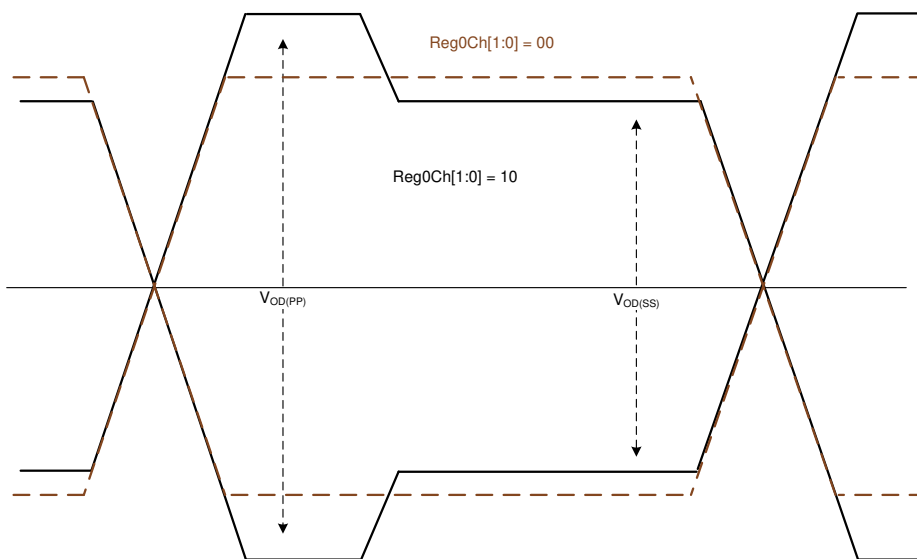


图 8-7. 6 dB Pre-Emphasis in DP-Mode

表 8-5. Swing and Pre-Emphasis Programming Based Upon 6 kΩ VSADJ Resistor

Mode	Global Control			Independent Lane Control		
	Reg09h[6] Lane CTL	Reg09[5] Mode CTL	P0_Reg0C[7:0]	Reg09h[6] Lane CTL	Reg09[5] Mode CTL	P0_Reg0C[7:0]
HDMI	0	0	8' h00	1	0	8' h00
DP SWG0, PRE0	0	1	8' h80	1	1	8' h80
DP SWG0, PRE1	0	1	8' hC1	1	1	8' hC1
DP SWG0, PRE2	0	1	8' h42	1	1	8' h42
DP SWG1, PRE0	0	1	8' hC0	1	1	8' hA0
DP SWG1, PRE1	0	1	8' hF1	1	1	8' h21
DP SWG1, PRE2	0	1	8' h52	1	1	8' h62
DP SWG2, PRE0	0	1	8' h20	1	1	8' h00
DP SWG2, PRE1	0	1	8' h51	1	1	8' h61

8.3.12 DP-Mode Description

The TDP158 has the ability to perform as a DisplayPort redriver under the right conditions. The TDP158 is put into this mode by setting reg09h[5] to 1. The device is now programmable through I²C only. As the transmitter is a DC coupled transmitter supporting TMDS some external circuits are required to level shift the signal to an AC-coupled DisplayPort signal, see 图 9-6. Note that the AUX lines bypass the TDP158. To set the device up correctly during link training, the TDP158 must be programmed using I²C. When this bit is set, the TDP158 does the following:

- Ignore SWAP function
- Ignore SIG_EN function
- Enable all four lanes and set to support 5.4 Gbps data rate
- Sets V_{OD} swing to the lowest level based on a 6 kΩ VSADJ resistor value
- Sets pre-emphasis to 0 dB
- Defaults to global lane control
- Can be set to independent lane control by setting P0_Reg09[6] to a 1. This should be done after implementing DP mode. Individual Lane control starts on P0_Reg30 through P0_Reg34 and also P0_Reg4E and 4F

For the system implementer to configure the TDP158 output to the properly requested levels during link training, the following registers are used.

- Reg0Ch[7:5] is a global V_{OD} swing control for all four lanes, see 表 8-5
- Reg0Ch[1:0] is a global Pre-emphasis control for all four lanes, see 表 8-5. This register works with Reg30h[7:6]
- Reg0D[6:3] is a global EQ control for all four lanes
- Reg30h[7:6] is to let the TDP158 know what the data rate is. This is used for the delay component for pre-emphasis signal.
- Reg30h[5:2] is used to turn on or off individual lanes

Power down states while in DP-Mode are implemented the same as if in normal operation. See the 节 6.7 for the outputs based upon the VSADJ 6 kΩ VSADJ resistor.

8.4 Device Functional Modes

8.4.1 DDC Training for HDMI 2.0 Data Rate Monitor

As part of discovery, the source reads the sink E-EDID information to understand the sink's capabilities. The supported data rate comes from the HDMI Forum Vendor Specific Data Block (HF-VSDB) MAX_TMDS_Character_Rate byte. Depending upon the value, the source will write to target address 0xA8 offset 0x20 bit1, TMDS_CLOCK_RATIO_STATUS. The TDP158 snoops the DDC link to determine the TMDS clock ratio status and thus sets its own TMDS_CLOCK_RATIO_STATUS bit accordingly. If a '1' is written by

the source the TMDS clock is 1/40 of TMDS bit period. If a ‘0’ is written, then the TMDS clock is 1/10 of TMDS bit period.

The TDP158 will always default to 1/10 of TMDS bit period unless a ‘1’ is written to address 0xA8 offset 0x20 bit 1 or during a read by the source this bit is set. This helps determine source termination when automatic source termination select is enabled. Otherwise this bit has no other impact on the TDP158. When HPD_SNK is de-asserted this bit is reset to default values of 0 if this feature is enabled. If the source does not write this bit to the sink or during the read the bit is not set the TDP158 will not set the output termination to 75 Ω to 150 Ω in support of HDMI 2.0. If the TDP158 has entered a power down state using HDP_SNK = low or OE = low this bit is cleared and will be set on a read or write where this bit is set. When DDC_TRAIN_SETDISABLE is 1’ b0 the TMDS_CLOCK_RATIO_STATUS bit will reflect the value of the DDC snoop. When DDC_TRAIN_SETDISABLE is 1’ b1 the TMDS_CLOCK_RATIO_STATUS bit is set by I²C and DDC snoop is ignored and thus automatic TERM control is ignored and must be manually set. To go back to snoop and automatic TERM control the DDC_TRAIN_SETDISABLE bit has to be cleared and TERM set back to automatic control.

8.4.2 DDC Functional Description

The TDP158 solves sink/source level issues by implementing a controller/target control mode for the DDC bus. When the TDP158 detects the start condition on the DDC bus from the SDA_SRC/SCL_SRC it transfers the data or clock signal to the SDA_SNK/SCL_SNK with little propagation delay. When SDA_SNK detects the feedback from the downstream device, the TDP158 pulls up or pulls down the SDA_SRC bus and delivers the signal to the source.

The DDC link defaults to 100 Kbps but can be set to various values including 400 Kbps by setting the correct value to address 22h through the I²C interface. The HPD goes to high impedance when VCC is under low power conditions, < 1.5 V.

备注

The TDP158 uses clock stretching for DDC transactions. As there are sources and sinks that do not perform this function correctly, a system may not work correctly as DDC transactions are incorrectly transmitted/received. To overcome this, a snoop configuration can be implemented where the SDA/SCL from the source is connected directly to the SDA/SCL pins. The TDP158 needs the SDA_SNK and SCL_SNK pins connected to the sink DDC pins so that the TMDS_CLOCK_RATIO_STATUS bit can be automatically set; otherwise, it will have to be set through I²C. For best noise immunity, the SDA_SRC and SCL_SRC pins should be connected to GND. Care must be taken when this configuration is being implemented as the voltage level for DDC between the source and sink may be different, 3.3 V versus 5 V.

8.5 Register Maps

The TDP158 local I²C interface is enabled when I²C_EN is high. The SCL_CTL and SDA_CTL terminals are used for I²C clock and data respectively. The TDP158 I²C interface conforms to the two-wire serial interface defined by the I²C Bus Specification, Version 2.1 (January 2000), and supports the fast mode transfer up to 400 Kbps. The device address byte is the first byte received following the START condition from the controller device. The 7 bit device address for TDP158 decides by the combination of A0/EQ1 and A1/EQ2. 表 8-6 clarifies the TDP158 target address.

表 8-6. TDP158 I2C Device Address Description

A1/A0	Bit 7 (MSB)	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0 (W/R)	HEX
00	1	0	1	1	1	1	0	0/1	BC/BD
01	1	0	1	1	1	0	1	0/1	BA/BB
10	1	0	1	1	1	0	0	0/1	B8/B9
11	1	0	1	1	0	1	1	0/1	B6/B7

The local I²C is 5-V tolerant, and no additional circuitry required. Local I²C buses run at 400 kHz supporting fast-mode I²C operation.

The following procedure is followed to write to the TDP158 I²C registers:

1. The controller initiates a write operation by generating a start condition (S), followed by the TDP158 7-bit address and a zero-value “W/R” bit to indicate a write cycle.
2. The TDP158 acknowledges the address cycle.
3. The controller presents the sub-address (I²C register within TDP158) to be written, consisting of one byte of data, MSB-first.
4. The TDP158 acknowledges the sub-address cycle.
5. The controller presents the first byte of data to be written to the I²C register.
6. The TDP158 acknowledges the byte transfer.
7. The controller may continue presenting additional bytes of data to be written, with each byte transfer completing with an acknowledge from the TDP158.
8. The controller terminates the write operation by generating a stop condition (P).

The following procedure is followed to read the TDP158 I²C registers:

1. The controller initiates a read operation by generating a start condition (S), followed by the TDP158 7-bit address and a one-value “W/R” bit to indicate a read cycle.
2. The TDP158 acknowledges the address cycle.
3. The TDP158 transmit the contents of the memory registers MSB-first starting at register 00h.
4. The TDP158 will wait for either an acknowledge (ACK) or a not-acknowledge (NACK) from the controller after each byte transfer; the I²C controller acknowledges reception of each data byte transfer.
5. If an ACK is received, the TDP158 transmits the next byte of data.
6. The controller terminates the read operation by generating a stop condition (P).

备注

Upon reset, the TDP158 sub-address will always be set to 0x00. When no sub-address is included in a read operation, the TDP158 sub-address will increment from previous acknowledged read or write data byte. If it is required to read from a sub-address that is different from the TDP158 internal sub-address, a write operation with only a sub-address specified is needed before performing the read operation.

Refer to [节 8.5.1](#) for TDP158 local I²C register descriptions. Reads from reserved fields or addresses that are not specified return zeros. The value written to reserved fields must match the value read from the reserved field to not impact device features or performance.

8.5.1 Local I²C Control BIT Access TAG Convention

Reads from reserved fields shall return zero, and writes to read-only reserved registers shall be ignored. Writes to reserved register which are marked with ‘W’ will produce unexpected behavior. All addresses not defined by this specification shall be considered reserved. Reads from these addresses shall return zero and writes shall be ignored.

8.5.2 BIT Access Tag Conventions

A table of bit descriptions is typically included for each register description that indicates the bit field name, field description, and the field access tags. The field access tags are described in [表 8-7](#).

表 8-7. Field Access Tags

Access Tag	Name	DESCRIPTION
R	Read	The field shall be read by software
W	Write	The field shall be written by software
S	Set	The field shall be set by a write of one. Writes of Zero to the field have no effect
C	Clear	The field shall be cleared by a write of one. Writes of Zero to the field have no effect
U	Update	Hardware may autonomously update this field
NA	No Access	Not accessible or not applicable

8.5.3 CSR Bit Field Definitions, DEVICE_ID (address = 00h≅07h)

图 8-8. DEVICE_ID

7	6	5	4	3	2	1	0
DEVICE_ID							
R							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-8. DEVICE_ID Field Descriptions

Bit	Field	Type	Default	Description
7:0		R		These fields return a string of ASCII characters "TDP158" followed by one space characters TDP158: Address 0x00 - 0x07 = {- 0x54" T", 0x44" D", 0x50" P", 0x31" 1", 0x35" 5", 0x38" 8, 0x20, 0x20

8.5.4 CSR Bit Field Definitions, REV_ID (address = 08h)

图 8-9. REV_ID Field Descriptions

7	6	5	4	3	2	1	0
REV_ID							
R							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-9. REV_ID

Bit	Field	Type	Default	Description
7:0	REV_ID	R	00000001	This field identifies the device revision. 00000001 - TDP158 Revision

8.5.5 CSR Bit Field Definitions - MISC CONTROL 09h (address = 09h)

图 8-10. MISC CONTROL 09h Field Descriptions

7	6	5	4	3	2	1	0
LANE_SWAP	Lane Control	DP-Mode	SIG_EN	PD_EN	HPD_AUTO_P WRDWN_DISA BLE	I2C_DR_CTL	
R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-10. MISC CONTROL 09h

Bit	Field	Type	Default	Description
7	LANE_SWAP	R/W	1' b0	This field Swaps the input lanes as per 图 8-4 和 节 8.3.4 and valid when in HDMI mode only. 0 - Disable (default) No Lane Swap 1 - Enable: Swaps both Input and Output Lanes
6	Lane Control	R/W	1' b0	See 节 8.3.3 0 - Global (Default) 1 - Independent Note: In default mode reg0C and reg0D control all lanes. When set to 1 each lane can be individually controlled for Swing, EQ, Pre-emphasis.

表 8-10. MISC CONTROL 09h (continued)

Bit	Field	Type	Default	Description
5	DP-Mode	R/W	1' b0	See 节 8.3.12 0 - Normal DP158 Operation (Default) 1 - All lanes behave as data lanes and full control through I2C only
4	SIG_EN	R/W	1' b1	This field enables the clock lane activity detect circuitry. See 节 8.3.7 0 - Disable Clock detector circuit closed and receiver always works in normal operation. 1 - Enable (default), Clock detector circuit will make the receiver automatically enter the standby state when no valid data detect.
3	PD_EN	R/W	1' b0	0 - Normal working (default) 1 - Forced Power down by I2C, Lowest Power state
2	HPD_AUTO_PWRDWN_DISABL	R/W	1' b0	0 - Automatically enters Power Down mode based on HPD_SNK (default) 1 - Will not automatically enter Power Down mode
1:0	I2C_DR_CTL	R/W	2' b10	I2C data rate supported for configuring device. 00 - 5 Kbps 01 - 10 Kbps 10 - 100 Kbps(Default) 11 - 400 Kbps

8.5.6 CSR Bit Field Definitions - MISC CONTROL 0Ah (address = 0Ah)

图 8-11. MISC CONTROL 0Ah Field Descriptions

7	6	5	4	3	2	1	0
Reserved	HPDSNK_GATE_EN	Reserved				SLEW_CTL_DATA	
R	R/W	R				R/W	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-11. MISC CONTROL 0Ah

Bit	Field	Type	Default	Description
7	Reserved	R	1' b0	Reserved
6	HPDSNK_GATE_EN	R/W	1' b0	The field set the HPD_SNK signal pass through to HPD_SRC or not and HPD_SRC whether held in the de-asserted state. 0 - HPD_SNK passed through to the HPD_SRC (default) 1 - HPD_SNK will not pass through to the HPD_SRC.
5:2	Reserved	R	4' b0000	Reserved
1:0	SLEW_CTL_DATA	R/W	2' b11	See 节 8.3.10 00 - Slowest \approx 110 01 - Mid-Range 1 \approx 95 10 - Mid-Range 2 \approx 80 ps 11 - Fastest (Default) \approx 60 ps Values are typical

8.5.7 CSR Bit Field Definitions - MISC CONTROL 0Bh (address = 0Bh)

图 8-12. MISC CONTROL 0Bh Field Descriptions

7	6	5	4	3	2	1	0
SLEW_CTL_CLK	Reserved	TERM		DDC_DR_SEL	TMDS_CLOCK_RATIO_STATUSES	DDC_TRAIN_SET_DISABLE	

图 8-12. MISC CONTROL 0Bh Field Descriptions (continued)

R/W	R	R/W	R/W	R/W/U	R/W
-----	---	-----	-----	-------	-----

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-12. MISC CONTROL 0Bh

Bit	Field	Type	Reset	Description
7:6	SLEW_CTL_CLK	R/W	2' b01	See # 8.3.10 00 - Slowest \approx 215 ps 01 - Mid-Range 1 (Default) \approx 185 ps 10 - Mid-Range 2 \approx 155 ps 11 - Fastest \approx 125 ps Values are typical
5	Reserved	R	1' b0	Reserved
4:3	TERM	R/W	2' b10	Controls termination for HDMI TX. See # 8.3.8 00 - 150 to 300 Ω 01 - No termination 10 - Follows TMDS_CLOCK_RATIO_STATUS bit (default). When = 1 termination value is 75 to 150 Ω : When = 0 No termination 11 - 75 to 150 Ω : Note: When TMDS_CLOCK_RATIO_STATUS bit reg0Bh[1] = 1 this register will automatically be set to 11 for 75 to 150 Ω but can be overwritten using this address
2	DDC_DR_SEL	R/W	1' b0	Defines the DDC output speed for DDC bridge 0 - 100 Kbps (default) 1 - 400 Kbps
1	TMDS_CLOCK_RATIO_STATUS	R/W/U	1' b0	This field is updated from snoop of I2C write to target address 0xA8 offset 0x20 bit 1 that occurred on the SDA_SRC/SCL_SRC interface. When bit 1 of address 0xA8 offset 0x20 is written to a 1' b1 or read as a 1' b1, then this field will be set to a 1' b1. When bit 1 of address 0xA8 offset 0x20 is written to a 1' b0, then this field will be set to a 1' b0. This field is reset to default value whenever HPD_SNK is de-asserted for greater than 2 ms. The main function of this bit is to automatically set the proper TX termination when value = 1. 0 - HDMI 1.4b (default) 1 - HDMI 2.0 Note 1. When DDC_TRAIN_SETDISABLE is 1' b0 this bit will reflect the value of the DDC snoop. Note 2. When DDC_TRAIN_SETDISABLE is 1' b1 this bit is set by I2C and DDC snoop is ignored. If this bit was set to 1 during snoop prior to the DDC_TRAIN_SETDISABLE being set to 1 it will be cleared to 0.
0	DDC_TRAIN_SETDISABLE	R/W	1' b0	This field indicate the DDC training block function status. 0 - DDC training enable (default) 1 - DDC training disable - DDC snoop disabled Note 1. When DDC_TRAIN_SETDISABLE is 1' b0 the TMDS_CLOCK_RATIO_STUATU bit will reflect the value of the DDC snoop. Note 2. When DDC_TRAIN_SETDISABLE is 1' b1, this bit is set by I2C and DDC snoop is ignored and thus automatic TERM control is ignored and must be manually set and TMDS_CLOCK_RATIO_STATUS bit will be cleared. Note 3. To go back to snoop and automatic TERM control this bit has to be cleared and TERM set back to automatic control.

8.5.8 CSR Bit Field Definitions – MISC CONTROL 0Ch (address = 0Ch)

图 8-13. MISC CONTROL 0Ch Field Descriptions

7	6	5	4	3	2	1	0
---	---	---	---	---	---	---	---

图 8-13. MISC CONTROL 0Ch Field Descriptions (continued)

VSWING_DATA	VSWING_CLK	HDMI_TWPST1[1:0]
R/W	R/W	R/W

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-13. MISC CONTROL 0Ch

Bit	Field	Type	Reset	Description
7:5	VSWING_DATA	R/W	3' b000	Data Output Swing Control 000 - Vsadj set (default) 001 - Increase by 7% 010 - Increase by 14% 011 - Increase by 21% 100 - Decrease by 30% 101 - Decrease by 21% 110 - Decrease by 14% 111 - Decrease by 7%
4:2	VSWING_CLK	R/W	3' b000	Clock Output Swing Control: Default is set by Vsadj resistor value and the value of reg0Dh[0]. 000 - Vsadj set (default) 001 - Increase by 7% 010 - Increase by 14% 011 - Increase by 21% 100 - Decrease by 30% 101 - Decrease by 21% 110 - Decrease by 14% 111 - Decrease by 7%
1:0	HDMI_TWPST1[1:0]	R/W	2' b00	HDMI Pre-emphasis 00 - No Pre-emphasis (default) 01 - 3.5 dB 10 - 6 dB 11 - Reserved NOTE: See Pre-emphasis Section for 6 dB explanation during normal operation supporting HDMI

8.5.9 CSR Bit Field Definitions, Equalization Control Register (address = 0Dh)

图 8-14. Equalization Control Register

7	6	5	4	3	2	1	0
Reserved	Data Lane Fixed EQ Values			Clock EQ Values		DIS_HDMI_2_SWG	
R	R/W			R/W			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-14. Equalization Control Register Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	R	1' b0	Reserved
6:3	Data Lane Fixed EQ Values	R/W	4' b0000	(Section 8.3.6 and 表 8-3 for values) 0000 - 0 dB (default)
2:1	Clock EQ Values	R/W	2' b00	00 - 0 dB (default) 01 - 1.5 dB 10 - 3 dB 11 - 4.5 dB

表 8-14. Equalization Control Register Field Descriptions (continued)

Bit	Field	Type	Reset	Description
0	DIS_HDMI 2_SWG	R/W	1' b0	Disables halving the clock output swing when entering HDMI 2.0 mode from TMDS_CLOCK_RATIO_STATUS. 0 - Disables TMDS_CLOCK_RATIO_STATUS control of the clock VOD so output swing is at full swing (default) 1 - Clock VOD is half of set values when TMDS_CLOCK_RATIO_STATUS states in HDMI 2.0 mode

8.5.10 CSR Bit Field Definitions, POWER MODE STATUS (address = 20h)

图 8-15. POWER MODE STATUS

7	6	5	4	3	2	1	0
Power Down Status Bit	Standby Status Bit	Loss of Signal Status Bit - LOS	Reserved				
R/U	R/U	R/U	R				

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-15. POWER MODE STATUS Field Descriptions

Bit	Field	Type	Reset	Description
7	Power Down Status Bit	R/U	1' b0	0 - Normal Operation 1 - Device in Power Down Mode.
6	Standby Status Bit	R/U	1' b0	0 - Normal Operation 1 - Device in Standby Mode
5	Loss of Signal Status Bit - LOS	R/U	1' b0	0 - Clock present 1 - No Clock present
4:0	Reserved	R	5' b00000	Reserved

8.5.11 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 30h)

See [# 8.3.12](#) and [# 8.3.3](#). Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one.

图 8-16. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
Data Rate Select	Clock Lane	Lane D0	Lane D1	Lane D2	Reserved		
R/W	R/W	R/W	R/W	R/W	R/W	R	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-16. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:6	Data Rate Select	R/W	2' b00	00 - 5.4 Gbps (default) 01 - 2.7 Gbps 10 - 1.62 Gbps 11 - Reserved
5	Clock Lane	R/W	1' b1	0 - Disabled 1 - Enabled (default)
4	Lane D0	R/W	1' b1	0 - Disabled 1 - Enabled (default)
3	Lane D1	R/W	1' b1	0 - Disabled 1 - Enabled (default)
2	Lane D2	R/W	1' b1	0 - Disabled 1 - Enabled (default)
1:0	Reserved	R	2' b00	Reserved

8.5.12 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 31h)

See Section [# 8.3.12](#) and [# 8.3.3](#). Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one.

图 8-17. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
VOD Swing Adjust for CLK Lane			Pre-emphasis Adjust for CLK Lane			Reserved	

图 8-17. DP-Mode and INDIVIDUAL LANE CONTROL (continued)

R/W	R/W	R/W
-----	-----	-----

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-17. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:5	VOD Swing Adjust for CLK Lane	R/W	3' b000	000 - Vsadj set (default) 001 - Increase by 7% 010 - Increase by 14% 011 - Increase by 21% 100 - Decrease by 30% 101 - Decrease by 21% 110 - Decrease by 14% 111 - Decrease by 7% Note: reg09h[6] = 1 otherwise all lanes are global control.
4:3	Pre-emphasis Adjust for CLK Lane	R/W	2' b00	00 - No Pre-emphasis (default) 01 - 3.5 dB Pre-emphasis. 10 - 6 dB Pre-emphasis 11 - Reserved Note 1. reg09h[6] = 1 otherwise all lanes are global control. Note 2. If in HDMI mode writes will be ignored and reg09h[7] SWAP = 0. No pre-emphasis on clock.
2:0	Reserved	R/W	3' b000	Reserved

8.5.13 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 32h)

See Section 节 8.3.12 and 节 8.3.3 Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-18. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
VOD Swing Adjust for D0 Lane			Pre-emphasis Adjust for D0 Lane		Reserved		
R/W			R/W		R/W		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-18. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:5	VOD Swing Adjust for D0 Lane	R/W	3' b000	000 - Vsadj set (default) 001 - Increase by 7% 010 - Increase by 14% 011 - Increase by 21% 100 - Decrease by 30% 101 - Decrease by 21% 110 - Decrease by 14% 111 - Decrease by 7% Note: reg09h[6] = 1 otherwise all lanes are global control.
4:3	Pre-emphasis Adjust for D0 Lane	R/W	2' b00	00 - No Pre-emphasis (default) 01 - 3.5 dB Pre-emphasis. 10 - 6 dB Pre-emphasis 11 - Reserved Note: reg09h[6] = 1 otherwise all lanes are global control.
2:0	Reserved	R/W	3' b000	Reserved

8.5.14 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 33h)

See Section 8.3.12 and 8.3.3 Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-19. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
VOD Swing Adjust for D1 Lane			Pre-emphasis Adjust for D1 Lane			Reserved	
R/W			R/W			R/W	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-19. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:5	VOD Swing Adjust for D1 Lane	R/W	3' b000	000 - Vsadj set (default) 001 - Increase by 7% 010 - Increase by 14% 011 - Increase by 21% 100 - Decrease by 30% 101 - Decrease by 21% 110 - Decrease by 14% 11 - Decrease by 7% Note: reg09h[6] = 1 otherwise all lanes are global control.
4:3	Pre-emphasis Adjust for D1 Lane	R/W	2' b00	00 - No Pre-emphasis (default) 01 - 3.5 dB Pre-emphasis. 10 - 6 dB Pre-emphasis 11 - Reserved Note: reg09h[6] = 1 otherwise all lanes are global control.
2:0	Reserved	R/W	3' b000	Reserved

8.5.15 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 34h)

See Section 8.3.12 and 8.3.3 Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-20. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
VOD Swing Adjust for D2 Lane			Pre-emphasis Adjust for D2 Lane			Reserved	
R/W			R/W			R/W	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-20. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:5	VOD Swing Adjust for D2 Lane	R/W	3' b000	000 - Vsadj set (default) 001 - Increase by 7% 010 - Increase by 14% 011 - Increase by 21% 100 - Decrease by 30% 101 - Decrease by 21% 110 - Decrease by 14% 11 - Decrease by 7% Note: reg09h[6] = 1 otherwise all lanes are global control.

表 8-20. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions (continued)

Bit	Field	Type	Reset	Description
4:3	Pre-emphasis Adjust for D2 Lane	R/W	2' b00	00 - No pre-emphasis (default) 01 - 3.5 dB pre-emphasis 10 - 6 dB pre-emphasis 11 - Reserved Note 1. reg09h[6] = 1 otherwise all lanes are global control. Note 2. If in HDMI mode writes will be ignored and reg09h[7] SWAP = 1. No pre-emphasis on clock.
2:0	Reserved	R/W	3' b000	Reserved

8.5.16 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 35h)

See Section [节 8.3.12](#) and [节 8.3.3](#) Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-21. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
Reserved							
R							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-21. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:0	Reserved	R	'h00	Reserved

8.5.17 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 4Dh)

See Section [节 8.3.12](#) and [节 8.3.3](#) Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-22. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
Reserved							
R							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-22. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:0	Reserved	R	'h00	Reserved

8.5.18 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 4Eh)

See Section [节 8.3.12](#) and [节 8.3.3](#) Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-23. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
Data Lane 1 Fixed EQ Values				Data Lane 2 Fixed EQ Values			
R/W				R/W			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-23. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:4	Data Lane 1 Fixed EQ Values	R/W	4' b0000	Section 8.3.6 and Table 8 2 for values 0000 - 0 dB (default)
3:0	Data Lane 2 Fixed EQ Values	R/W	4' b0000	Section 8.3.6 and Table 8 2 for values 0000 - 0 dB (default)

8.5.19 CSR Bit Field Definitions, DP-Mode and INDIVIDUAL LANE CONTROL (address = 4Fh)

See [节 8.3.12](#) and [节 8.3.3](#). Note: DP-Mode is valid only when DP-Mode Register P0_Reg09[5] is set to one

图 8-24. DP-Mode and INDIVIDUAL LANE CONTROL

7	6	5	4	3	2	1	0
CLK Lane Fixed EQ Values				Data Lane 0 Fixed EQ Values			
R/W				R/W			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-24. DP-Mode and INDIVIDUAL LANE CONTROL Field Descriptions

Bit	Field	Type	Reset	Description
7:4	CLK Lane Fixed EQ Values	R/W	4' b0000	Section 8.3.6 and Table 8 2 for values 0000 - 0 dB (default)
3:0	Data Lane 0 Fixed EQ Values	R/W	4' b0000	Section 8.3.6 and Table 8 2 for values 0000 - 0 dB (default)

9 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

9.1 Application Information

The TDP158 was designed to work mainly in source applications such as Blu-Ray DVD players, gaming systems, desktops, notebooks, or AVRs. The following sections provide design consideration for various types of applications.

9.2 Typical Application

图 9-1 provides a schematic representation of what is considered a standard implementation.

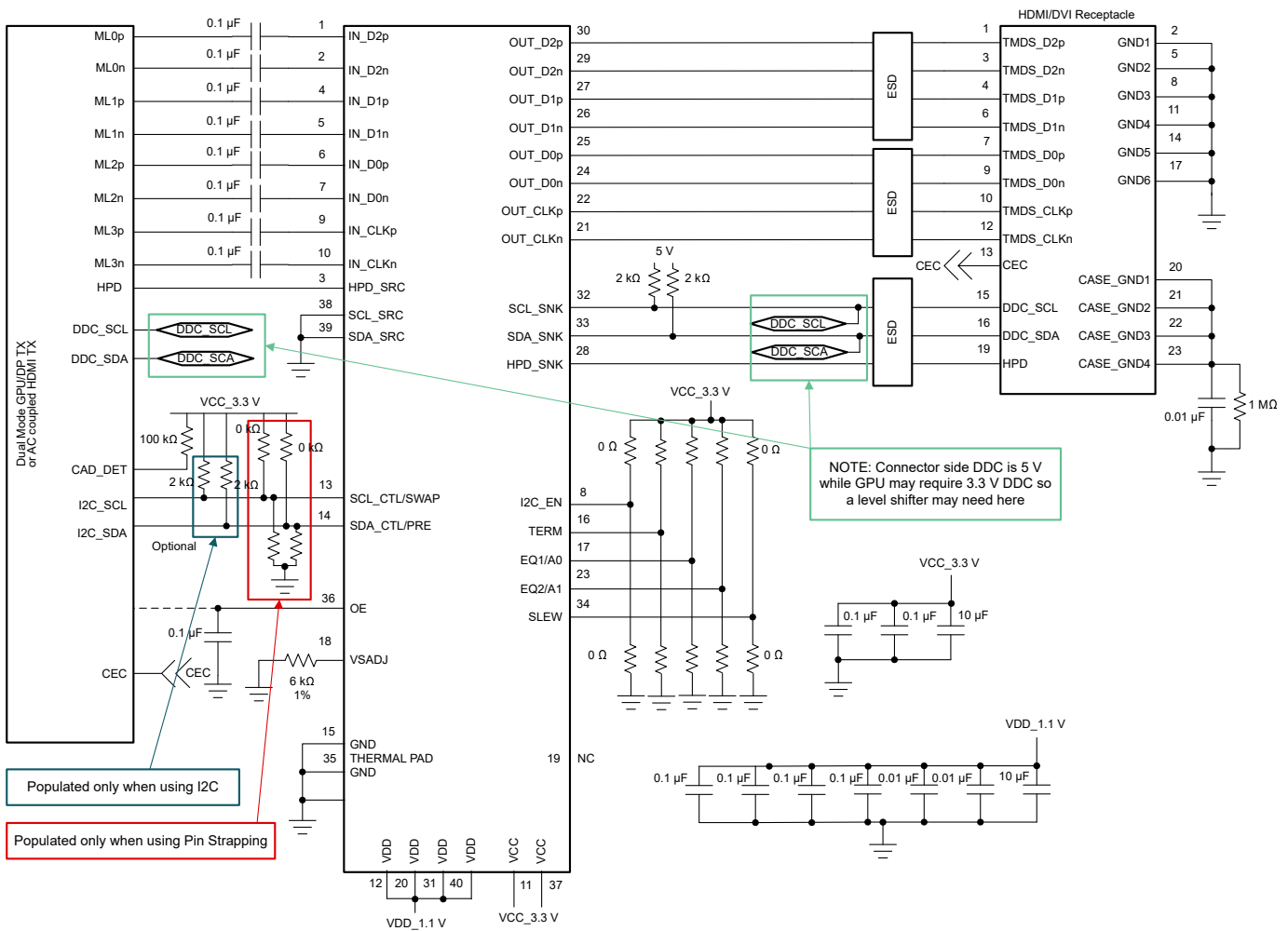


图 9-1. TDP158 in Source Side Application

9.2.1 Design Requirements

The TDP158 can be designed into many different applications. In all the applications there are certain requirements for the system to work properly. Two voltage rails are required to support the lowest power consumption possible. The OE pin must have a 0.1- μ F capacitor to ground. This pin can be driven by a processor but the pin needs to change states after the voltage rails have stabilized. Using the I²C is the best way to configure the device, but pin strapping is also provided as I²C, which is not available in all cases. As sources may have many different naming conventions, it is necessary to confirm that the link between the source and the TDP158 are correctly mapped. A swap function is provided for the input pins in case signaling is reversed between source and the device. The following control pin values are based upon driving pins with a microcontroller; otherwise, the shown pullup/down configuration meets the device levels. The following table provides information on the expected values to perform properly.

For this design, use the parameters shown in [表 9-1](#).

表 9-1. Design Parameters

Design Parameter	Value
V_{CC}	3.3 V
V_{DD}	1.1 V
Main Link Input Voltage	$V_{ID} = 0.15$ to 1.4 Vpp
Control Pin Max Voltage for Low	Connect to $1\text{ k}\Omega$ pulldown resistor to GND
Control Pin Voltage Range Mid	Connect to $1\text{ k}\Omega$ pulldown resistor to GND
Control Pin Min Voltage for High	Connect to $1\text{ k}\Omega$ pullup resistor to V_{CC}
$R_{(VSADJ)}$ Resistor	6.49 $\text{k}\Omega$ 1%

9.2.2 Detailed Design Procedure

9.2.2.1 Source Side

The TDP158 is a signal conditioning device that provides several forms of signal conditioning to support compliance for HDMI or DVI at a source connector. These forms of signal conditioning are accomplished using receive equalization, retiming, and output driver configurability. The transmitter will drive 1" - 2" of board trace and connector when compliance is required at the connector.

To design in the TDP158 the following need to be understood for a source side application:

- Determine the loss profile between the GPU/chipset and the HDMI /DVI connector.
- Based upon this loss profile and signal swing determine optimal location for the TDP158, to pass source electrical compliance. Usually within 1" - 2" of the connector.
- Use the typical application [图 9-1](#) for information on control pin resistors.
- The TDP158 has a receiver equalizer but can also be configured using EQ1 and EQ2 control pins.
- Set the V_{OD} , pre-emphasis, termination, and edge rate levels appropriately to support compliance by using the appropriate VSADJ resistor value and setting SDA_CTL/PRE, TERM and SLEW control pins.
- The thermal pad must be connected to ground.
- See schematics in [图 9-1](#) on recommended decouple caps from V_{CC} pins to ground.

9.2.2.2 DDC Pull Up Resistors

This section is for information only and subject to change depending upon system implementation. The pull-up resistor value is determined by two requirements:

1. The maximum sink current of the I²C buffer:

The maximum sink current is 3 mA or slightly higher for an I²C driver supporting standard-mode I²C operation.

$$R_{UP(min)} = \frac{V_{CC}}{I_{sink}} \quad (1)$$

2. The maximum transition time on the bus:

The maximum transition time, T, of an I²C bus is set by an RC time constant, where R is the pull-up resistor value, and C is the total load capacitance. The parameter, k, can be calculated from [方程式 3](#) by solving for t, the times at which certain voltage thresholds are reached. Different input threshold combinations introduce different values of t. [表 9-2](#) summarizes the possible values of k under different threshold combinations.

$$T = k \times RC \quad (2)$$

$$V(t) = V_{DD} \times (1 - e^{-\frac{t}{RC}}) \quad (3)$$

表 9-2. Value k upon Different Input Threshold Voltages

V _{th} -V _{th+}	0.7 V _{CC}	0.65 V _{CC}	0.6 V _{CC}	0.55 V _{CC}	0.5 V _{CC}	0.45 V _{CC}	0.4 V _{CC}	0.35 V _{CC}	0.3 V _{CC}
0.1 V _{CC}	1.0986	0.9445	0.8109	0.6931	0.5878	0.4925	0.4055	0.3254	0.2513
0.15 V _{CC}	1.0415	0.8873	0.7538	0.6360	0.5306	0.4353	0.3483	0.2683	0.1942
0.2 V _{CC}	0.9808	0.8267	0.6931	0.5754	0.4700	0.3747	0.2877	0.2076	0.1335
0.25 V _{CC}	0.9163	0.7621	0.6286	0.5108	0.4055	0.3102	0.2231	0.1431	0.0690
0.3 V _{CC}	0.8473	0.6931	0.5596	0.4418	0.3365	0.2412	0.1542	0.0741	

From [方程式 1](#), R_{up}(min) = 5.5 V/3 mA = 1.83 kΩ to operate the bus under a 5-V pull-up voltage and provide less than 3 mA when the I²C device is driving the bus to a low state. If a higher sink current, for example 4 mA, is allowed, R_{up}(min) can be as low as 1.375 kΩ.

If DDC working at standard mode of 100 Kbps, the maximum transition time T is fixed, 1 μs, and using the k values from [表 9-2](#), the recommended maximum total resistance of the pull-up resistors on an I²C bus can be calculated for different system setups. If DDC working in fast mode of 400 Kbps, the transition time should be set at 300 ns according to I²C specification.

To support the maximum load capacitance specified in the HDMI spec, C_(cable)(max) = 700 pF, C_(source) = 50 pF, C_l = 50 pF, R(max) can be calculated as shown in [表 9-3](#).

表 9-3. Pull-Up Resistor Upon Different Threshold Voltages and 800-pF Loads

V _{th} -V _{th+}	0.7 V _{CC}	0.65 V _{CC}	0.6 V _{CC}	0.55 V _{CC}	0.5 V _{CC}	0.45 V _{CC}	0.4 V _{CC}	0.35 V _{CC}	0.3 V _{CC}	UNIT
0.1 V _{CC}	1.14	1.32	1.54	1.8	2.13	2.54	3.08	3.84	4.97	kΩ
0.15 V _{CC}	1.2	1.41	1.66	1.97	2.36	2.87	3.59	4.66	6.44	kΩ
0.2 V _{CC}	1.27	1.51	1.8	2.17	2.66	3.34	4.35	6.02	9.36	kΩ
0.25 V _{CC}	1.36	1.64	1.99	2.45	3.08	4.03	5.6	8.74	18.12	kΩ
0.3 V _{CC}	1.48	1.8	2.23	2.83	3.72	5.18	8.11	16.87	—	kΩ

To accommodate the 3-mA drive current specification, a narrower threshold voltage range is required to support a maximum 800-pF load capacitance for a standard-mode I²C bus.

9.2.3 Application Curves

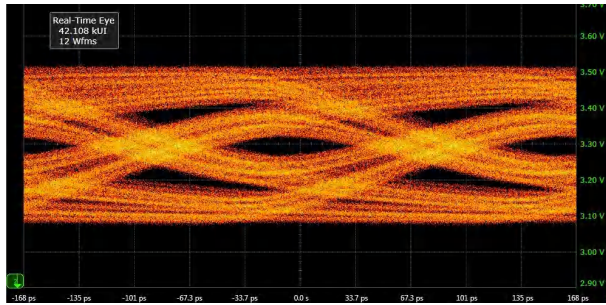


图 9-2. High Loss Input Eye -20” 4 mil Trace at TDP158 Pin

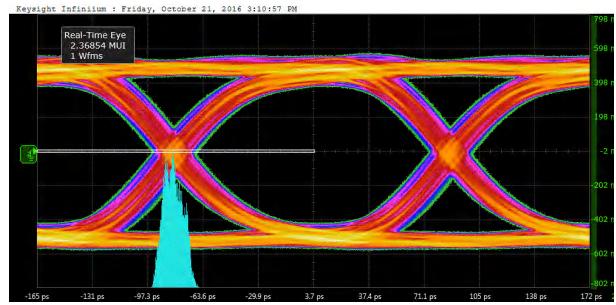


图 9-3. Output Eye from High Loss Input Eye at TDP158 Pin

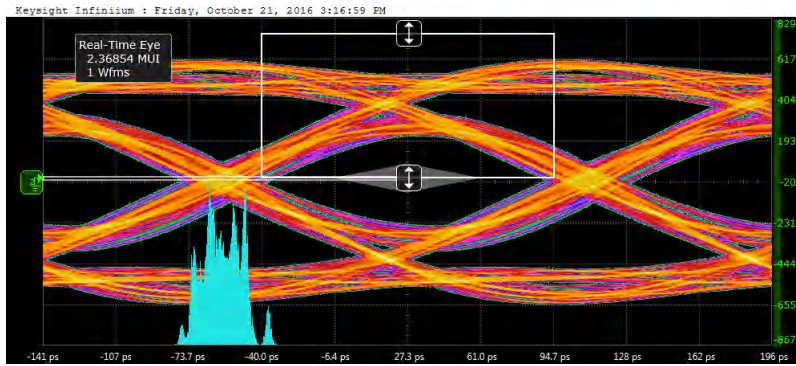


图 9-4. HDMI 2 Compliance Eye from High Loss Input Eye

9.2.4 Application with DDC Snoop

9.2.4.1 Source Side HDMI Application

In source side applications, the TDP158 takes an AC-coupled HDMI signal and provides signal conditioning and level shifting to support TMDS signaling. [Figure 9-5](#) provides an example of a DDC snoop version. Notes in both schematics provide important system design considerations. To help reduce overall EMI in a system the VCC and VDD decoupling caps need to be as close to the pins as possible. The drawings shown one set but multiple sets may be needed for each pin.

Control pins should be tied to 1 kΩ pullup to VCC, 1 kΩ pulldown to GND, or left floating. Drawings show 0-Ω resistors as this provides flexibility. In noisy systems a 0.1-μF capacitor to GND may reduce glitches on these pins and are not shown in the drawings. As [Figure 9-5](#) shows, connect the DDC source and sink pins to GND as the SCL/SDA_SRC if an application requires the DDC source and sink pins to be completely bypassed. If this is done, then the TX termination must be controlled by the TERM pin or through I²C.

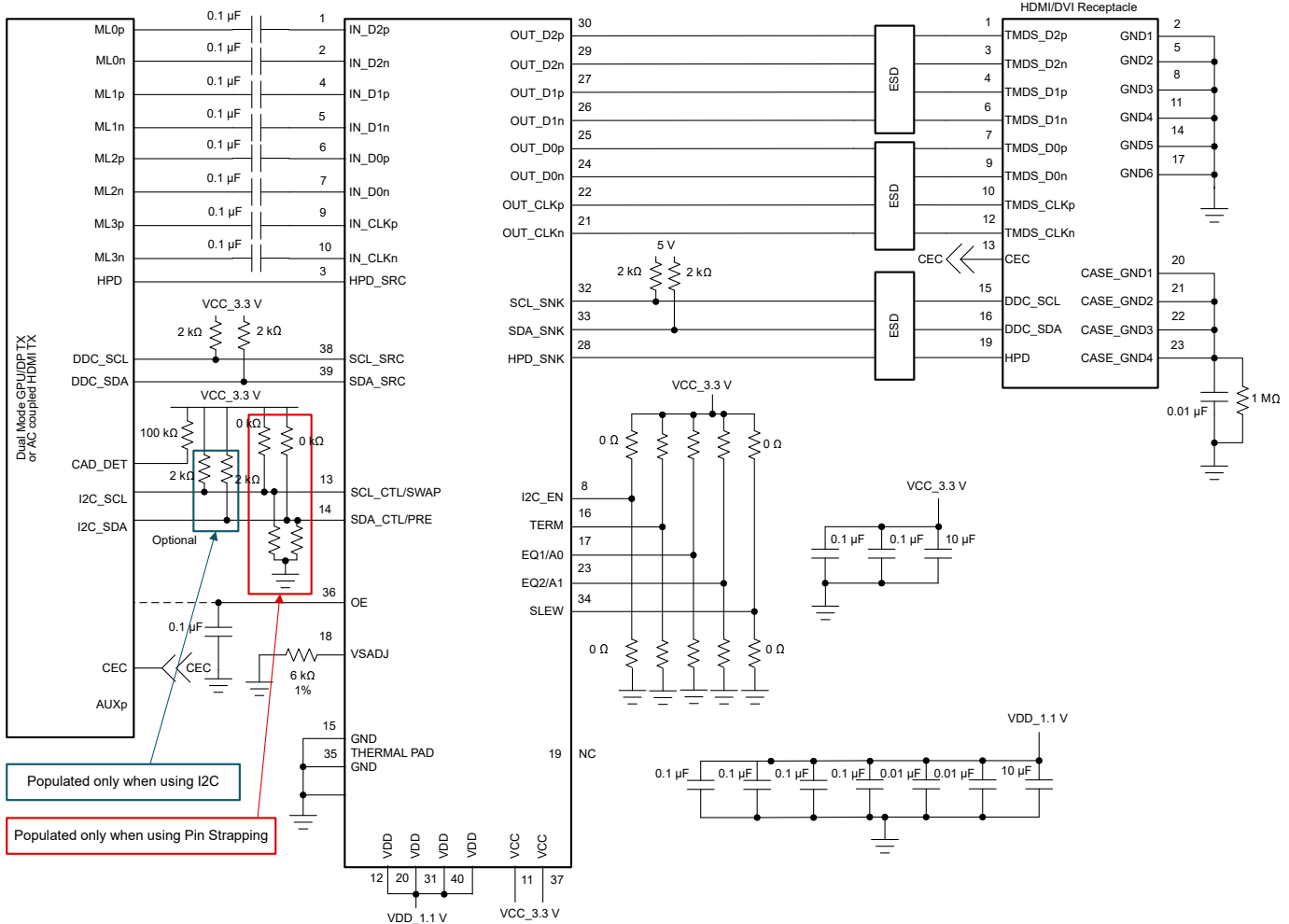


Figure 9-5. TDP158 Source Side Application with DDC Snoop

9.2.5 9.1.2 Source Side HDMI /DP Application Using DP-Mode

The TDP158 has a special mode that will allow the device to support either HDMI or DP applications. The device is put into this mode by setting reg09h[5] to 1. The device will self-configure with the following settings and become I²C programmable only. The TDP158 does not support automatic Link Training for DisplayPort. AUX channel bypasses device.

- All four lanes are turned on and configured for 5.4 Gbps data rate.
- Sets V_{OD} swing to ≈ 410 mV (This value is based upon a VSADJ value of 6 k Ω).
- Reg0Ch[7:5] is used to control VOD swing for all lanes.
- Reg0Ch[1:0] is used to control pre-emphasis for all lanes.
- Reg30h[7:2] is used to turn on or off individual lanes as well as informing the TDP158 what the data rate is. This is used for the delay component for pre-emphasis signal.

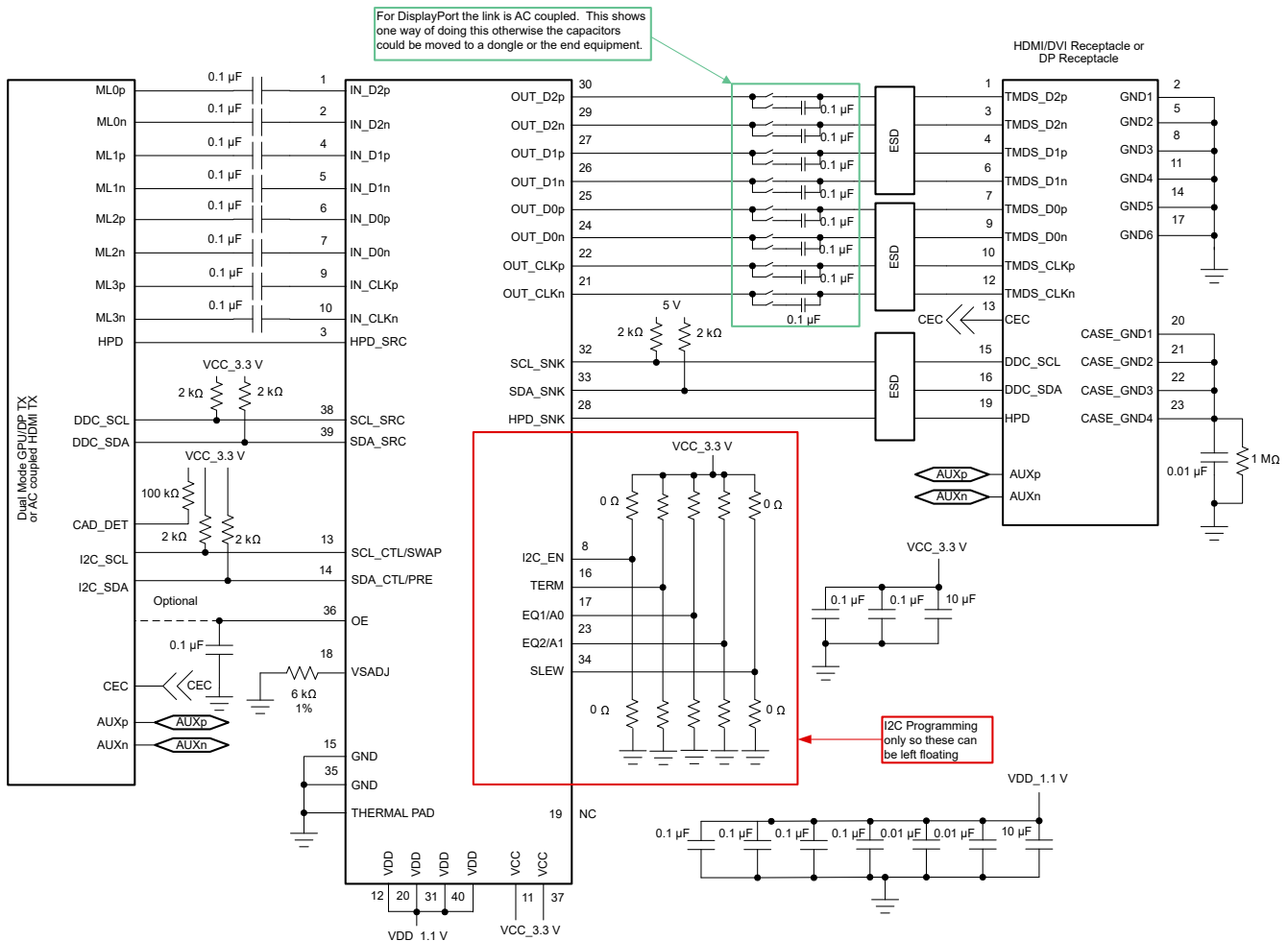


图 9-6. TDP158 in Dual Role Source Side Application

10 Power Supply Recommendations

10.1 Power Management

To minimize the power consumption of customer application, TDP158 used the dual power supply. V_{CC} is 3.3 V with 10% range to support the I/O voltage. The V_{DD} is 1.1 V with $\approx 5\%$ range to supply the internal digital control circuit. TDP158 operates in 3 different working states.

- Power Down mode:
 - When OE = Low, the device will put itself into the lowest power state by shutting down all function blocks.
 - OE re-asserted means the pin transitions from low to high. Transitioning the OE pin from L → H creates a reset. If the device is programmed through I²C, then it must be reprogrammed.
 - Writing a 1 to register 09h[3].
 - OE = High, HPD_SNK = Low for > 2 ms
- Standby mode:
 - HPD_SNK = High but no valid clock signal detect on clock lane.
- Normal operation:
 - When HPD assert, the device output will enable based on the signal detector circuit result.
 - HPD_SRC = HPD_SNK in all conditions. The HPD channel operational when V_{CC} over 3 V.

备注

When the TDP158 is put into a power down state the I²C registers are cleared. This is important as the TMDS_CLOCK_RATIO_STATUS bit will be cleared. If cleared and HDMI 2.0 resolutions are to be supported the TDP158 expects the source to write a 1 to this bit location. If the read has the bit set, the TDP158 will set this bit; otherwise, the source termination must be set manually.

10.2 Standby Power

The TDP158/I implement a two stage standby power process.

Stage 1: If there is no signal on the clock line, then the maximum $I_{VCC} \approx 7$ mA and maximum $I_{VDD} \approx 7$ mA.

Stage 2: If a signal (like a noise or clock signal) is on the clock line, then the TDP158 investigates the clock line for 3 μ s to 5 μ s and detects if a signal is present.

- If a clock is detected, then the TDP158 will go into normal operation.
- If it is determined that no clock is present, then the TDP158 will re-enter stage 1.

In stage 2; maximum $I_{VCC} \approx 7$ mA and maximum $I_{VDD} \approx 27$ mA.

表 10-1. Power Modes

INPUTS				STATUS					
OE	HPD_SNK	Reg09[2]	IN_CLK	HPD_SRC	IN_Dx	SDA/SCL_CTL	OUT_Dx OUT_CLK	DDC	Mode
L	X	X	X	H	High-Z	Disable	High-Z	Disabled	Power Down Mode
H	X	1	X	HPD_SNK	RX Active	Active	TX Active	Active	Normal operation
H	X	1	No Valid TMDS Clock	HPD_SNK	D0-D2 Disabled IN_CLK Active	Active	High-Z	Active	Standby Mode (Squelch waiting)
H	X	1	Valid TMDS Clock	HPD_SNK	RX Active	Active	TX Active	Active	Normal operation
H	H	0	No Valid TMDS Clock	HPD_SNK	D0-D2 Disabled IN_CLK Active	Active	High-Z	Active	Standby Mode (Squelch waiting)
H	H	0	Valid TMDS Clock	HPD_SNK	RX Active	Active	TX Active	Active	Normal operation

11 Layout

11.1 Layout Guidelines

For the TDP158 on a high-K board, it is required to solder the PowerPAD™ onto the thermal land to ground. A thermal land is the area of solder-tinned-copper underneath the PowerPAD™ package. On a high-K board the TDP158 can operate over the full temperature range by soldering the PowerPAD™ onto the thermal land. On a low-K board, for the device to operate across the temperature range on a low-K board, a 1-oz Cu trace connecting the GND pins to the thermal land must be used. A simulation shows $R_{\theta JA} = 100.84^{\circ}\text{C/W}$ allowing 545 mW power dissipation at 70°C ambient temperature. A general PCB design guide for PowerPAD packages is provided in the document [SLMA002](#). TI recommends using a four layer stack up at a minimum to accomplish a low-EMI PCB design. TI recommends six layers as the TDP158 is a two voltage rail device.

- Routing the high-speed TMDS traces on the top layer avoids the use of vias, avoids the introduction of their inductances, and allows for clean interconnects from the HDMI connectors to the Redriver inputs and outputs. It is important to match the electrical length of these high speed traces to minimize both inter-pair and intra-pair skew.
- Placing a solid ground plane next to the high-speed single layer establishes controlled impedance for transmission link interconnects and provides an excellent low - inductance path for the return current flow.
- Placing a power plane next to the ground plane creates an additional high-frequency bypass capacitance.
- Routing slower speed control signals on the bottom layer allows for greater flexibility as these signal links usually have margin to tolerate discontinuities such as vias.
- If an additional supply voltage plane or signal layer is needed, add a second power/ground plane system to the stack to keep symmetry. This makes the stack mechanically stable and prevents it from warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high frequency bypass capacitance significantly.

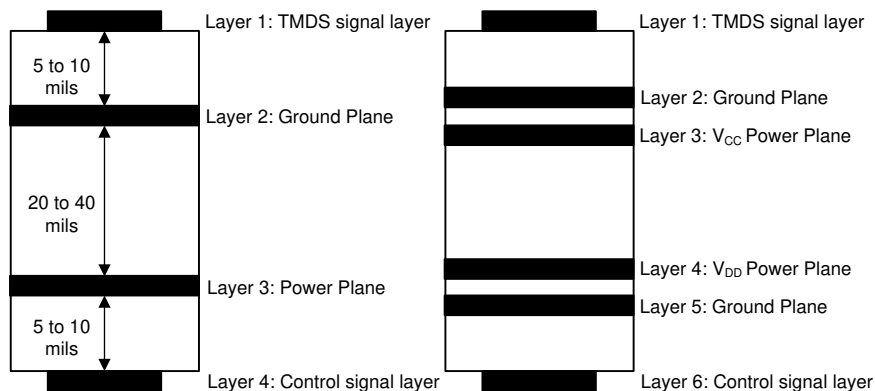
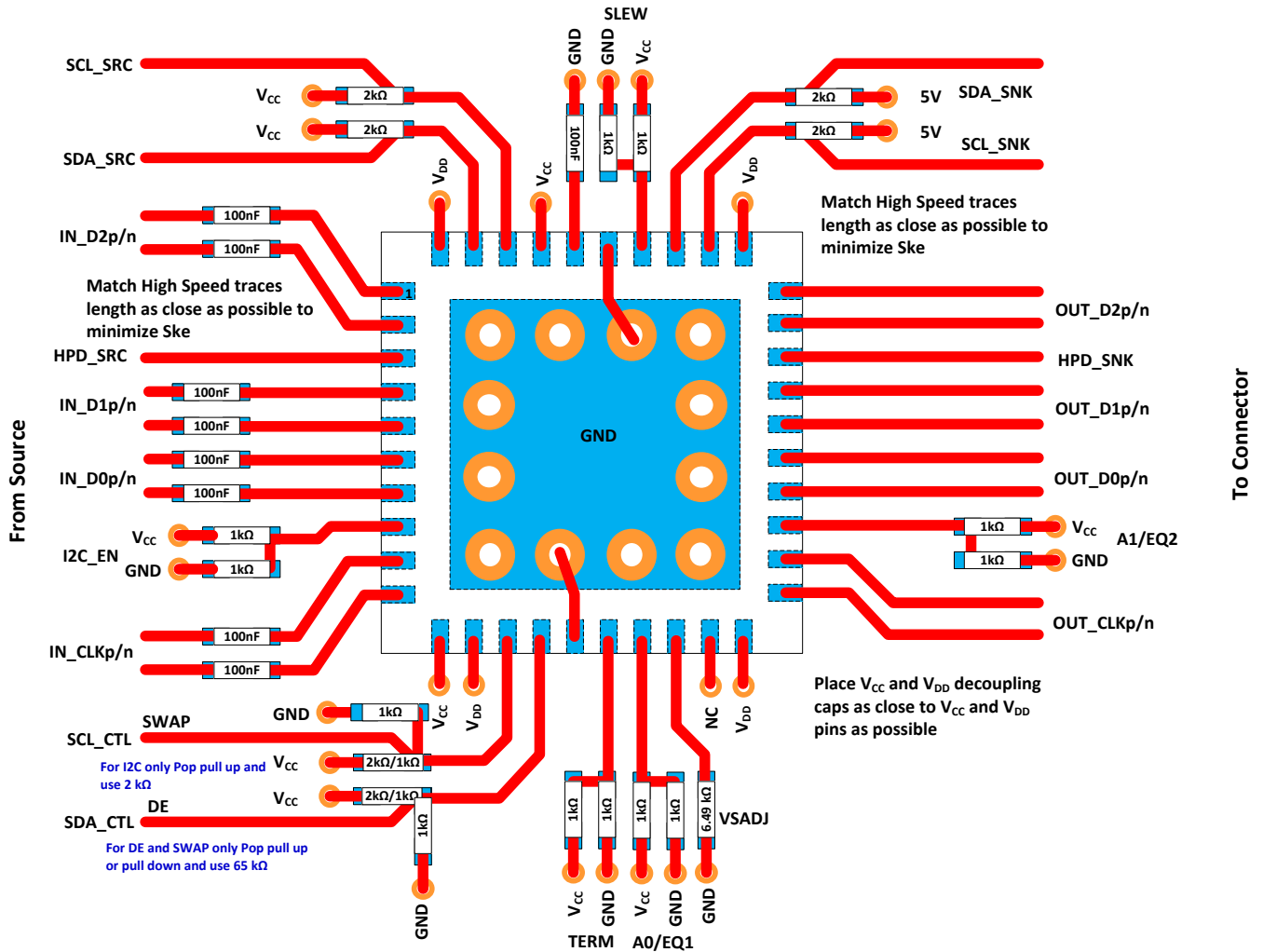


图 11-1. Recommended 4 - or 6 - Layer PCB Stack

11.2 Layout Example



The differential input lanes and differential output lanes should be separated as close to the TDP158 as feasible to minimize crosstalk. Adding a ground flood plain between each differential lane further reduces crosstalk and thus improves signal integrity at high speed data rates.

11-2. Example Layout for Source Side Application

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [PowerPAD Thermally Enhanced Package](#)
- [HDMI] High-definition Multimedia Interface CTS Version 1.4b October, 2011
- [HDMI] High-definition Multimedia Interface CTS Version 2.0o June 2016
- [HDMI] High-definition Multimedia Interface Specification Version 1.4b October, 2011
- [HDMI] High-definition Multimedia Interface Specification Version 2.0 September 4, 2013
- [I2C] The I2C-Bus specification version 2.1 January 2000

12.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.3 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

12.4 Trademarks

TMDS™ is a trademark of Wabtec Holding Corp.

HDMI™ is a trademark of HDMI Licensing Administrator, Inc.

DisplayPort™ is a trademark of Video Electronics Standards Association.

Blu-ray™ is a trademark of Blu-ray Disc Association.

PowerPAD™ and TI E2E™ are trademarks of Texas Instruments.

所有商标均为其各自所有者的财产。

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TDP158RSBR	ACTIVE	WQFN	RSB	40	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 85	TDP158	Samples
TDP158RSBT	ACTIVE	WQFN	RSB	40	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 85	TDP158	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TDP158RSBR	WQFN	RSB	40	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
TDP158RSBT	WQFN	RSB	40	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TDP158RSBR	WQFN	RSB	40	3000	367.0	367.0	35.0
TDP158RSBT	WQFN	RSB	40	250	210.0	185.0	35.0

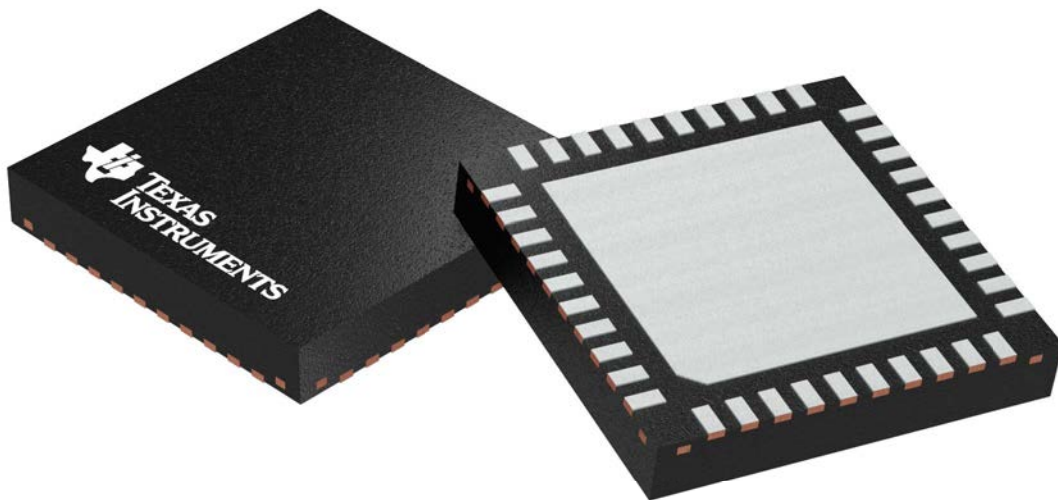
GENERIC PACKAGE VIEW

RSB 40

WQFN - 0.8 mm max height

5 x 5 mm, 0.4 mm pitch

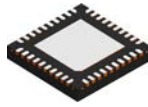
PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4207182/D

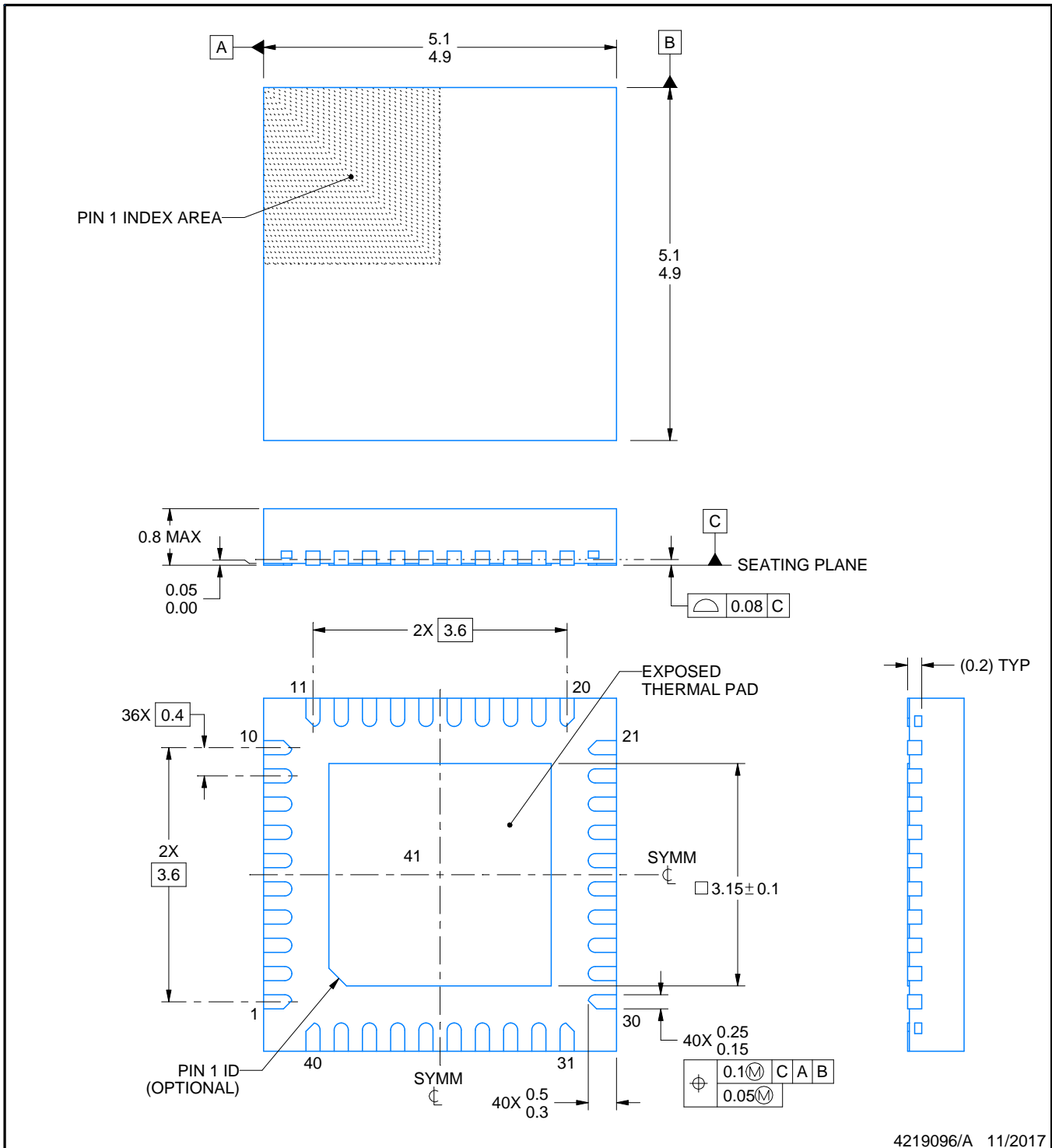
RSB0040E



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

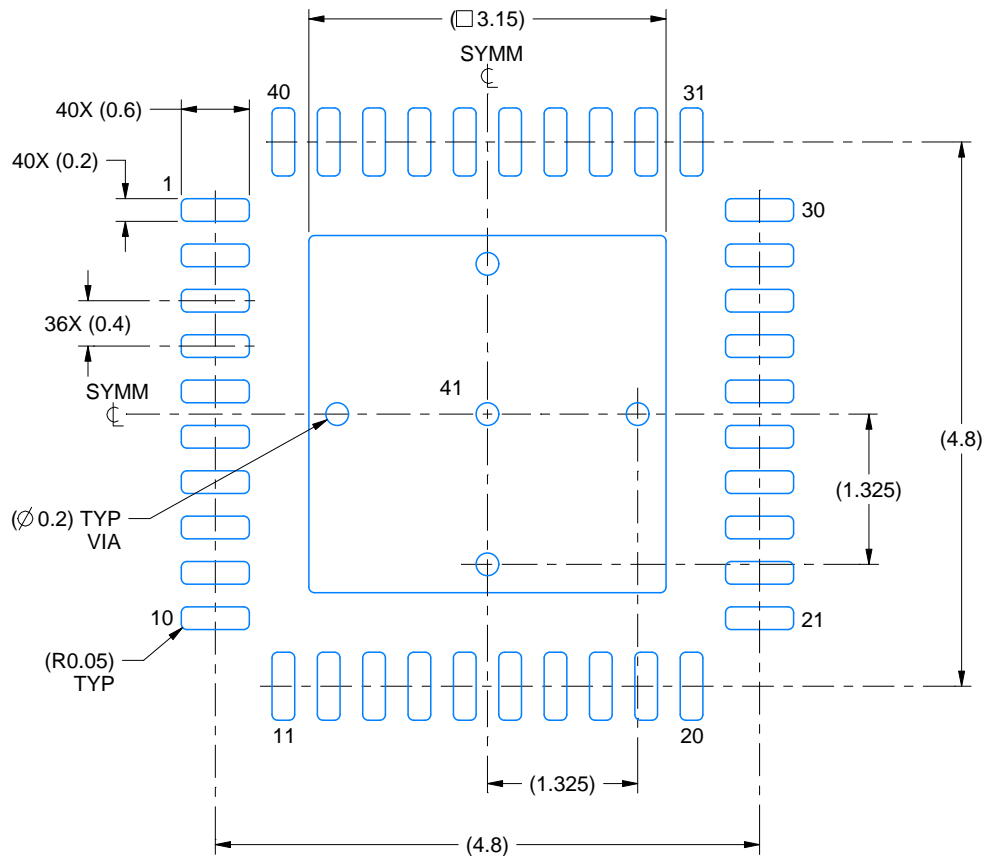
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

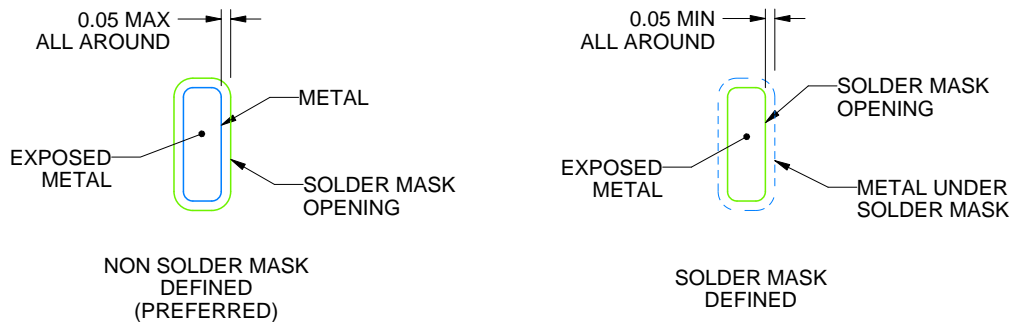
RSB0040E

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4219096/A 11/2017

NOTES: (continued)

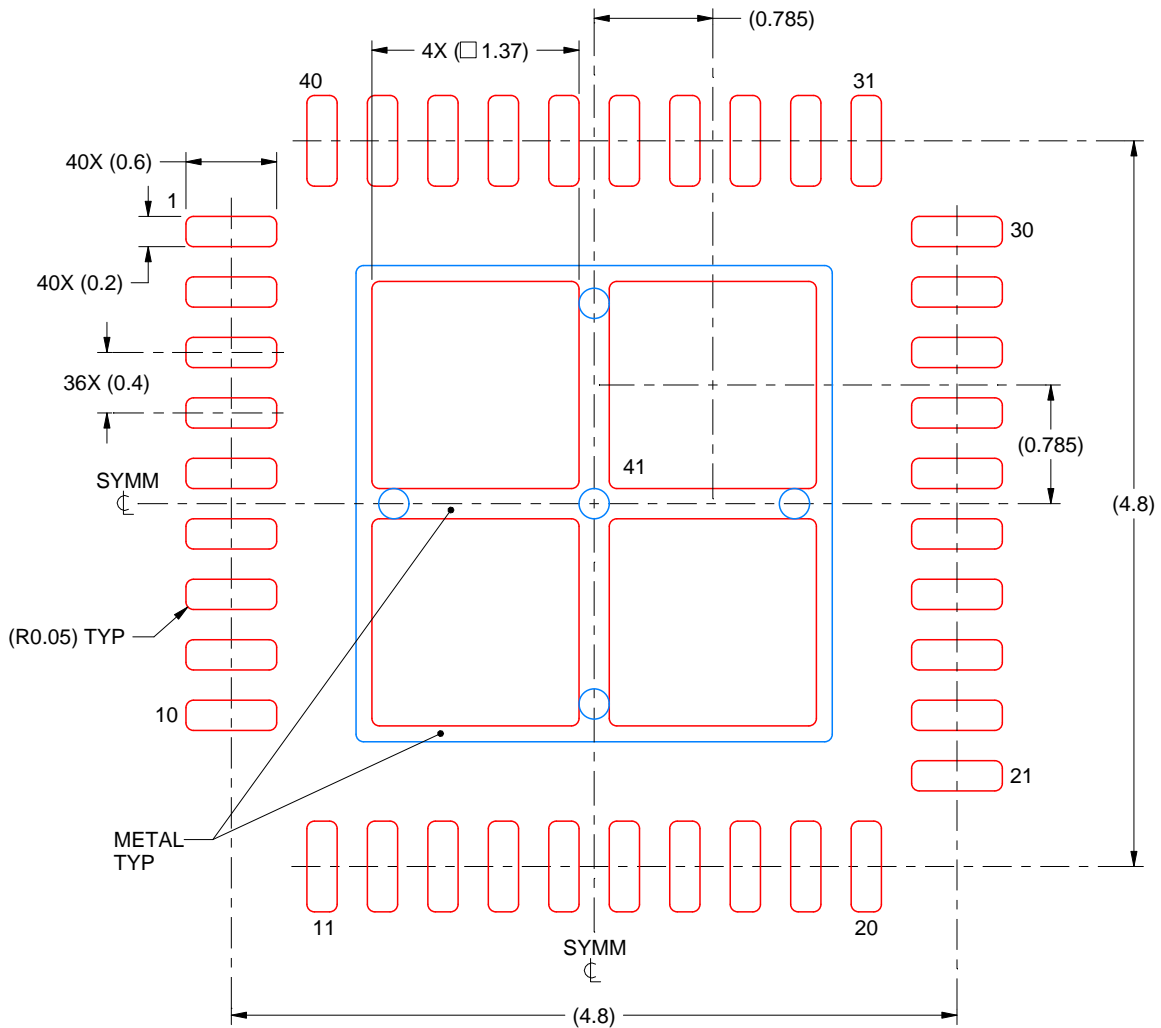
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RSB0040E

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL

EXPOSED PAD 41
75% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:20X

4219096/A 11/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

重要声明和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

Copyright © 2023，德州仪器 (TI) 公司